AUTOMOTIVE, 125°C OPERATION, 36 V, SUPPLY VOLTAGE DIVIDED OUTPUT, WINDOW VOLTAGE DETECTOR WITH SENSE PIN REVERSE CONNECTION PROTECTION

Rev.1.2_00

This IC, developed using CMOS technology, is a high-accuracy window voltage detector with the supply voltage divided output that detects undervoltage and overvoltage. The detection voltage and release voltage are fixed internally with an accuracy of ±1.5%.

Apart from the power supply pin, the detection voltage input pin (SENSE pin) is also prepared, so the output is stable even if the SENSE pin voltage (V_{SENSE}) falls to 0 V. The SENSE pin also has a built-in reverse connection protection circuit that reduces current in the SENSE pin during a reverse connection. The release signal can be delayed by setting a capacitor externally, and the release delay time accuracy is ±15% (C_D = 3.3 nF). The output form is Nch open-drain output.

The supply voltage divided output is prepared in this IC. The supply voltage divided output is a function that divides the V_{SENSE} into $V_{SENSE}/6$, $V_{SENSE}/8$, $V_{SENSE}/12$ or $V_{SENSE}/14$ and outputs the voltage. For example, this function makes it possible that the IC connects to a low voltage microcontroller A/D converter directly and the microcontroller monitors a battery voltage.

ABLIC Inc. offers FIT rate calculated based on actual customer usage conditions in order to support customer functional safety design.

For more information regarding our FIT rate calculation, contact our sales representatives.

Caution   This product can be used in vehicle equipment and in-vehicle equipment. Before using the product for these purposes, it is imperative to contact our sales representatives.

■ Features

Detector block

- Detection voltage: Undervoltage detection voltage   4.0 V to 10.0 V (0.05 V step)
       Overvoltage detection voltage   16.0 V to 18.0 V (0.1 V step)
- Detection voltage accuracy: Undervoltage detection voltage   ±1.5%
       Overvoltage detection voltage   ±1.5%
- Hysteresis width selectable from "Available" / "Unavailable":   "Available": 5.0%, 10.0%
       "Unavailable": 0%
- Release delay time accuracy: ±15% (C_D = 3.3 nF)
- Output form: Nch open-drain output

Supply voltage divider block

- Output voltage: $V_{PMOUT} = V_{SENSE}/6$ (S-191L Series L / M / N type)
       $V_{PMOUT} = V_{SENSE}/8$ (S-191L Series P / Q / R type)
       $V_{PMOUT} = V_{SENSE}/12$ (S-191N Series L / M / N type)
       $V_{PMOUT} = V_{SENSE}/14$ (S-191N Series P / Q / R type)
- Output capacitor (C_{PM}):   A ceramic capacitor can be used (0.1 μF to 0.22 μF).
- Built-in enable circuit: Ensures long battery life.

Overall

- Current consumption: During supply voltage divided output operates   1.3 μA typ.
       During supply voltage divided output stops   0.9 μA typ.
- Built-in reverse connection protection circuit: Reduces current in the SENSE pin during a reverse connection.
- Operation voltage range: 3.0 V to 36.0 V
- Operation temperature range: Ta = −40°C to +125°C
- Lead-free (Sn 100%), halogen-free
- Withstand 45 V load dump
- AEC-Q100 qualified[1]

[1]. Contact our sales representatives for details.
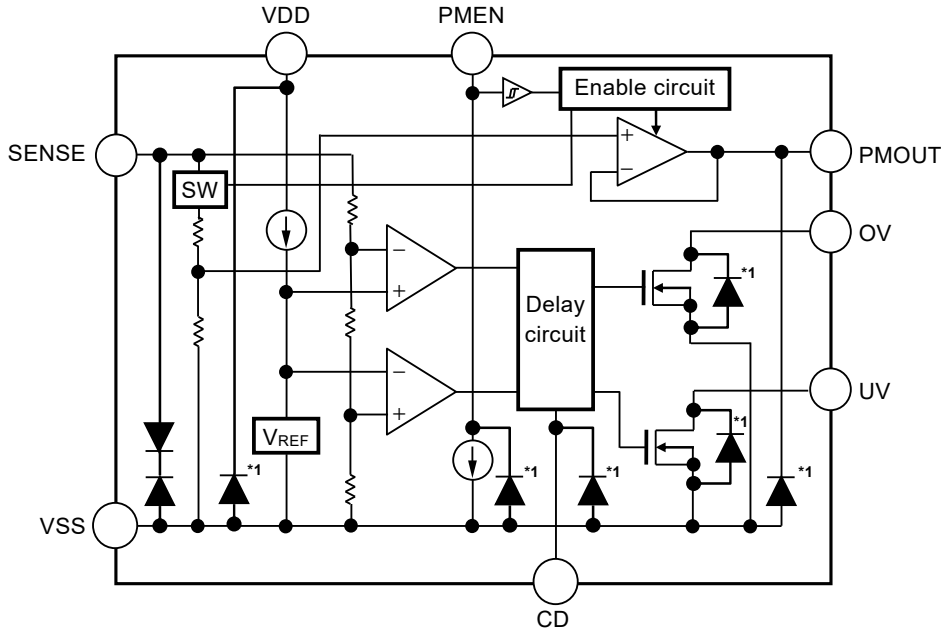
■ Applications

- Overvoltage detection of power supply for automotive electric component
- Automotive battery voltage detection
- For automotive use (engine, transmission, suspension, ABS, related-devices for EV / HEV / PHEV, etc.)

■ Packages

- HTMSOP-8
- HSNT-8(2030)

■ Block Diagrams

1. S-191L/191N Series L / P type

*1. Parasitic diode

Figure 1
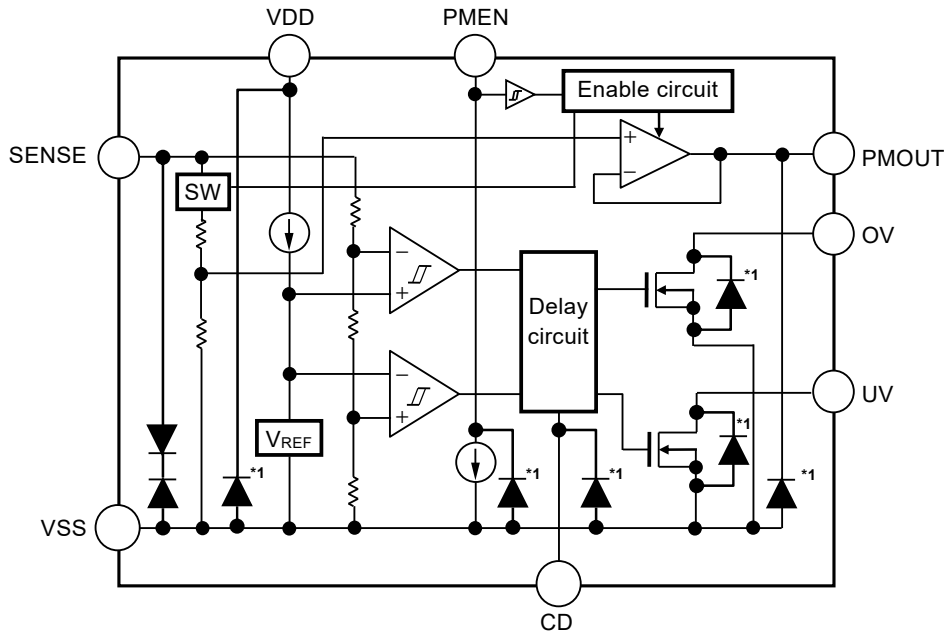
1. 1 S-191L Series

Table 1

Product Type	Output Voltage of Supply Voltage Divider Block (V_{PMOUT})	Hysteresis Width (V_{UVHYS}, V_{OVHYS})	PMEN Pin Input Logic	UV, OV Pin Output Form	UV, OV Pin Output Logic
L type	$V_{SENSE}/6$	0%	Active "H"	Nch open-drain output	Active "L"
P type	$V_{SENSE}/8$	0%	Active "H"	Nch open-drain output	Active "L"

1. 2 S-191N Series

Table 2

Product Type	Output Voltage of Supply Voltage Divider Block (V_{PMOUT})	Hysteresis Width (V_{UVHYS}, V_{OVHYS})	PMEN Pin Input Logic	UV, OV Pin Output Form	UV, OV Pin Output Logic
L type	$V_{SENSE}/12$	0%	Active "H"	Nch open-drain output	Active "L"
P type	$V_{SENSE}/14$	0%	Active "H"	Nch open-drain output	Active "L"

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Rev.1.2_00   **S-191L/191NxxxxA Series**

2. S-191L/191N Series M / N / Q / R type

*1. Parasitic diode

Figure 2
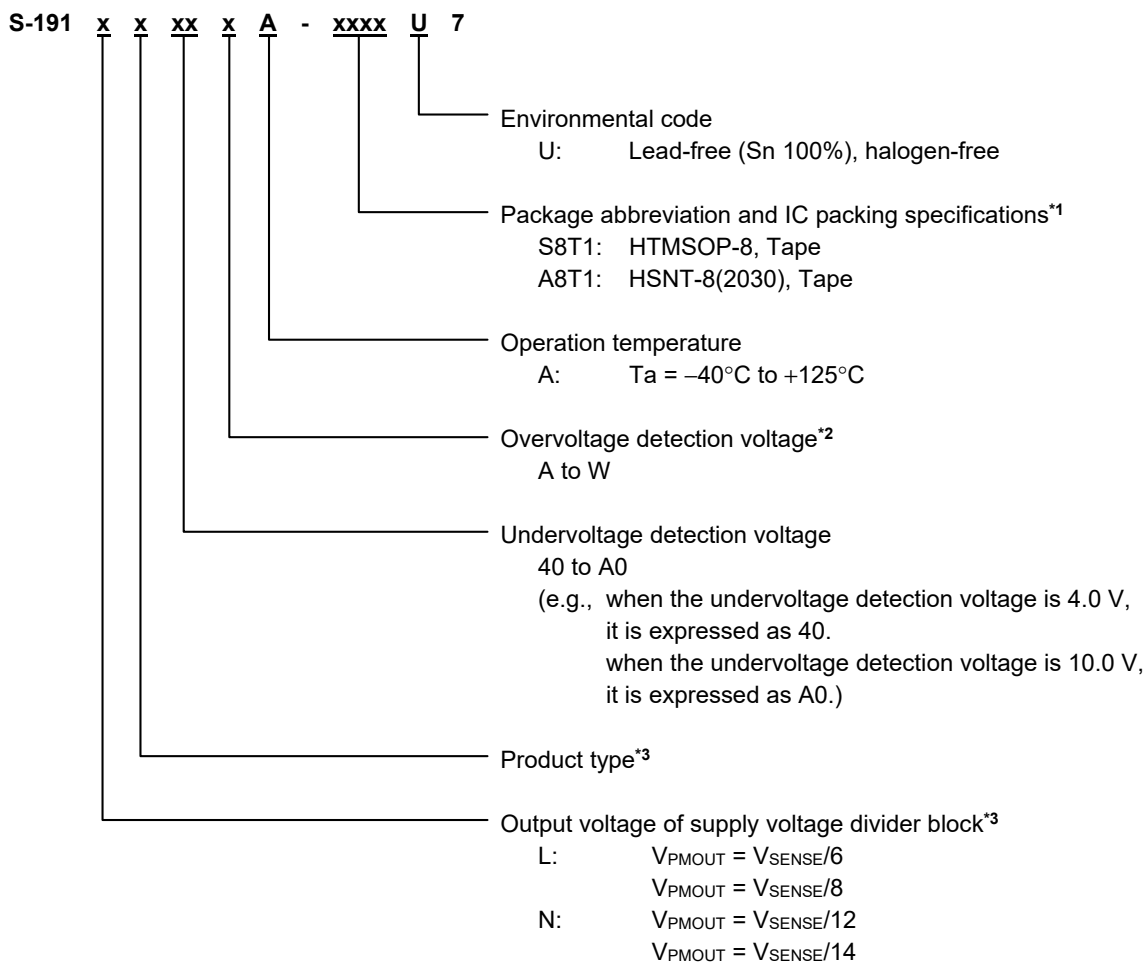
2. 1 S-191L Series

Table 3

Product Type	Output Voltage of Supply Voltage Divider Block (V_{PMOUT})	Hysteresis Width (V_{UVHYS}, V_{OVHYS})	PMEN Pin Input Logic	UV, OV Pin Output Form	UV, OV Pin Output Logic
M type	$V_{SENSE}/6$	5.0%	Active "H"	Nch open-drain output	Active "L"
N type	$V_{SENSE}/6$	10.0%	Active "H"	Nch open-drain output	Active "L"
Q type	$V_{SENSE}/8$	5.0%	Active "H"	Nch open-drain output	Active "L"
R type	$V_{SENSE}/8$	10.0%	Active "H"	Nch open-drain output	Active "L"

2. 2 S-191N Series

Table 4

Product Type	Output Voltage of Supply Voltage Divider Block (V_{PMOUT})	Hysteresis Width (V_{UVHYS}, V_{OVHYS})	PMEN Pin Input Logic	UV, OV Pin Output Form	UV, OV Pin Output Logic
M type	$V_{SENSE}/12$	5.0%	Active "H"	Nch open-drain output	Active "L"
N type	$V_{SENSE}/12$	10.0%	Active "H"	Nch open-drain output	Active "L"
Q type	$V_{SENSE}/14$	5.0%	Active "H"	Nch open-drain output	Active "L"
R type	$V_{SENSE}/14$	10.0%	Active "H"	Nch open-drain output	Active "L"

■ AEC-Q100 Qualified

This IC supports AEC-Q100 for operation temperature grade 1.
Contact our sales representatives for details of AEC-Q100 reliability specification.

■ Product Name Structure

1. Product name

S-191 x x xx x A - xxxx U 7

Environmental code
U: Lead-free (Sn 100%), halogen-free

Package abbreviation and IC packing specifications[1]
S8T1: HTMSOP-8, Tape
A8T1: HSNT-8(2030), Tape

Operation temperature
A: Ta = −40°C to +125°C

Overvoltage detection voltage[2]
A to W

Undervoltage detection voltage
40 to A0
(e.g., when the undervoltage detection voltage is 4.0 V,
it is expressed as 40.
when the undervoltage detection voltage is 10.0 V,
it is expressed as A0.)

Product type[3]

Output voltage of supply voltage divider block[3]
L: $V_{PMOUT} = V_{SENSE}/6$
$V_{PMOUT} = V_{SENSE}/8$
N: $V_{PMOUT} = V_{SENSE}/12$
$V_{PMOUT} = V_{SENSE}/14$

[1]. Refer to the tape drawing.
[2]. Refer to **Table 5** for the overvoltage detection voltage.
[3]. Refer to "**2. Function list of product types**".

Table 5

Overvoltage Detection Voltage	Symbol	Overvoltage Detection Voltage	Symbol	Overvoltage Detection Voltage	Symbol
16.0 V	A	16.7 V	H	17.4 V	Q
16.1 V	B	16.8 V	J	17.5 V	R
16.2 V	C	16.9 V	K	17.6 V	S
16.3 V	D	17.0 V	L	17.7 V	T
16.4 V	E	17.1 V	M	17.8 V	U
16.5 V	F	17.2 V	N	17.9 V	V
16.6 V	G	17.3 V	P	18.0 V	W

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2. Function list of product types

2. 1 S-191L Series

Table 6

Product Type	Output Voltage of Supply Voltage Divider Block (V_{PMOUT})	Hysteresis Width (V_{UVHYS}, V_{OVHYS})	PMEN Pin Input Logic	UV, OV Pin Output Form	UV, OV Pin Output Logic
L type	$V_{SENSE}/6$	0%	Active "H"	Nch open-drain output	Active "L"
M type	$V_{SENSE}/6$	5.0%	Active "H"	Nch open-drain output	Active "L"
N type	$V_{SENSE}/6$	10.0%	Active "H"	Nch open-drain output	Active "L"
P type	$V_{SENSE}/8$	0%	Active "H"	Nch open-drain output	Active "L"
Q type	$V_{SENSE}/8$	5.0%	Active "H"	Nch open-drain output	Active "L"
R type	$V_{SENSE}/8$	10.0%	Active "H"	Nch open-drain output	Active "L"

2. 2 S-191N Series

Table 7

Product Type	Output Voltage of Supply Voltage Divider Block (V_{PMOUT})	Hysteresis Width (V_{UVHYS}, V_{OVHYS})	PMEN Pin Input Logic	UV, OV Pin Output Form	UV, OV Pin Output Logic
L type	$V_{SENSE}/12$	0%	Active "H"	Nch open-drain output	Active "L"
M type	$V_{SENSE}/12$	5.0%	Active "H"	Nch open-drain output	Active "L"
N type	$V_{SENSE}/12$	10.0%	Active "H"	Nch open-drain output	Active "L"
P type	$V_{SENSE}/14$	0%	Active "H"	Nch open-drain output	Active "L"
Q type	$V_{SENSE}/14$	5.0%	Active "H"	Nch open-drain output	Active "L"
R type	$V_{SENSE}/14$	10.0%	Active "H"	Nch open-drain output	Active "L"

3. Packages

Table 8 Package Drawing Codes

Package Name	Dimension	Tape	Reel	Land
HTMSOP-8	FP008-A-P-SD	FP008-A-C-SD	FP008-A-R-SD	FP008-A-L-SD
HSNT-8(2030)	PP008-A-P-SD	PP008-A-C-SD	PP008-A-R-SD	PP008-A-L-SD

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■ Pin Configurations

1. HTMSOP-8

Top view

Table 9

Figure 3

Pin No.	Symbol	Description
1	PMEN	Supply voltage divided output enable pin
2	VDD	Voltage input pin
3	PMOUT	Supply voltage divided output pin
4	SENSE	Detection voltage input pin
5	CD[*2]	Connection pin for release delay time adjustment capacitor
6	VSS	GND pin
7	UV	Undervoltage detection output pin
8	OV	Overvoltage detection output pin

*1. Connect the heat sink of backside at shadowed area to the board, and set electric potential GND.
   However, do not use it as the function of electrode.
*2. Connect a capacitor between the CD pin and the VSS pin. The release delay time can be adjusted according to the capacitance.

2. HSNT-8(2030)

Top view

Table 10

Figure 4

Pin No.	Symbol	Description
1	PMEN	Supply voltage divided output enable pin
2	VDD	Voltage input pin
3	PMOUT	Supply voltage divided output pin
4	SENSE	Detection voltage input pin
5	CD[*2]	Connection pin for release delay time adjustment capacitor
6	VSS	GND pin
7	UV	Undervoltage detection output pin
8	OV	Overvoltage detection output pin

*1. Connect the heat sink of backside at shadowed area to the board, and set electric potential GND.
   However, do not use it as the function of electrode.
*2. Connect a capacitor between the CD pin and the VSS pin. The release delay time can be adjusted according to the capacitance.

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■ Absolute Maximum Ratings

Table 11

(Ta = −40°C to +125°C unless otherwise specified)

Item		Symbol	Absolute Maximum Rating	Unit
Power supply voltage		V_{DD}	V_{SS} − 0.3 to V_{SS} + 45.0	V
SENSE pin voltage	S-191L Series L / M / N type	V_{SENSE}	V_{SS} − 30.0 to V_{SS} + 42.0	V
	S-191L Series P / Q / R type		V_{SS} − 30.0 to V_{SS} + 45.0	V
	S-191N Series L / M / N type		V_{SS} − 30.0 to V_{SS} + 45.0	V
	S-191N Series P / Q / R type		V_{SS} − 30.0 to V_{SS} + 45.0	V
CD pin input voltage		V_{CD}	V_{SS} − 0.3 to V_{DD} + 0.3 ≤ V_{SS} + 7.0	V
PMEN pin input voltage		V_{PMEN}	V_{SS} − 0.3 to V_{SS} + 45.0	V
Output voltage	Detector block	V_{UV}	V_{SS} − 0.3 to V_{SS} + 45.0	V
		V_{OV}	V_{SS} − 0.3 to V_{SS} + 45.0	V
	Supply voltage divider block	V_{PMOUT}	V_{SS} − 0.3 to V_{DD} + 0.3 ≤ V_{SS} + 7.0	V
Output current		I_{UV}	25	mA
		I_{OV}	25	mA
		I_{PMOUT}	2	mA
Junction temperature		T_j	−40 to +150	°C
Operation ambient temperature		T_{opr}	−40 to +125	°C
Storage temperature		T_{stg}	−40 to +150	°C

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

■ Thermal Resistance Value

Table 12

Item	Symbol	Condition		Min.	Typ.	Max.	Unit
Junction-to-ambient thermal resistance[1]	θ_{JA}	HTMSOP-8	Board A	–	159	–	°C/W
			Board B	–	113	–	°C/W
			Board C	–	39	–	°C/W
			Board D	–	40	–	°C/W
			Board E	–	30	–	°C/W
		HSNT-8(2030)	Board A	–	181	–	°C/W
			Board B	–	135	–	°C/W
			Board C	–	40	–	°C/W
			Board D	–	42	–	°C/W
			Board E	–	32	–	°C/W

[1]. Test environment: compliance with JEDEC STANDARD JESD51-2A

Remark Refer to "■ **Power Dissipation**" and "**Test Board**" for details.

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■ Electrical Characteristics

1. Detector block

Table 13

(Ta = −40°C to +125°C unless otherwise specified)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit	Test Circuit
Undervoltage detection voltage[*1]	V_{UVDET}	V_{DD} = 13.5 V, 4.0 V ≤ $V_{UVDET(S)}$ ≤ 10.0 V	$V_{UVDET(S)}$ × 0.985	$V_{UVDET(S)}$	$V_{UVDET(S)}$ × 1.015	V	1
Overvoltage detection voltage[*2]	V_{OVDET}	V_{DD} = 13.5 V, 16.0 V ≤ $V_{OVDET(S)}$ ≤ 18.0 V	$V_{OVDET(S)}$ × 0.985	$V_{OVDET(S)}$	$V_{OVDET(S)}$ × 1.015	V	1
Undervoltage hysteresis width[*3]	V_{UVHYS}	L / P type (V_{UVHYS} = 0%)	–	V_{UVDET} × 0.00	–	V	1
		M / Q type (V_{UVHYS} = 5.0%)	V_{UVDET} × 0.04	V_{UVDET} × 0.05	V_{UVDET} × 0.06	V	1
		N / R type (V_{UVHYS} = 10.0%)	V_{UVDET} × 0.09	V_{UVDET} × 0.10	V_{UVDET} × 0.11	V	1
Overvoltage hysteresis width[*3]	V_{OVHYS}	L / P type (V_{OVHYS} = 0%)	–	V_{OVDET} × 0.00	–	V	1
		M / Q type (V_{OVHYS} = 5.0%)	V_{OVDET} × 0.04	V_{OVDET} × 0.05	V_{OVDET} × 0.06	V	1
		N / R type (V_{OVHYS} = 10.0%)	V_{OVDET} × 0.09	V_{OVDET} × 0.10	V_{OVDET} × 0.11	V	1
Operation voltage	V_{DD}	–	3.0	–	36.0	V	1
Output current	I_{OUT}	UV pin Nch driver, V_{DD} = 3.0 V, V_{DS}[*4] = 0.1 V, V_{SENSE} = $V_{UVDET(S)}$ − 1 V	0.60	–	–	mA	2
		OV pin Nch driver, V_{DD} = 3.0 V, V_{DS}[*4] = 0.1 V, V_{SENSE} = $V_{OVDET(S)}$ + 1 V	0.60	–	–	mA	2
Leakage current	I_{LEAK}	UV pin Nch driver, V_{DD} = 36 V, V_{UV} = 36 V, V_{SENSE} = 13.5 V	–	–	2.0	μA	2
		OV pin Nch driver, V_{DD} = 36 V, V_{OV} = 36 V, V_{SENSE} = 13.5 V	–	–	2.0	μA	2
Detection response time[*5]	t_{RESET}	–	–	80	200	μs	3
Release delay time[*6]	t_{DELAY}	C_D = 3.3 nF	8.5	10.0	11.5	ms	3
SENSE pin resistance	R_{SENSE}	V_{PMEN} = 0 V	6.8	–	200	MΩ	7
CD pin discharge ON resistance	R_{CDD}	V_{DD} = 3.0 V, V_{CD} = 0.7 V	0.15	–	0.90	kΩ	–

*1. V_{UVDET}: Actual undervoltage detection voltage value, $V_{UVDET(S)}$: Set undervoltage detection voltage value

*2. V_{OVDET}: Actual overvoltage detection voltage value, $V_{OVDET(S)}$: Set overvoltage detection voltage value

*3. The undervoltage release voltage (V_{UVREL}) and the overvoltage release voltage (V_{OVREL}) are as follows.
　　L / P type (hysteresis width "Unavailable"):　　　V_{UVREL} = V_{UVDET}, V_{OVREL} = V_{OVDET}
　　M / N / Q / R type (hysteresis width "Available"):　V_{UVREL} = V_{UVDET} + V_{UVHYS}, V_{OVREL} = V_{OVDET} − V_{OVHYS}

*4. V_{DS}: Drain-to-source voltage of the output transistor

*5. The time period from when the pulse voltage of $V_{UVDET(S)}$ + 1.0 V → $V_{UVDET(S)}$ − 1.0 V or $V_{OVDET(S)}$ − 1.0 V → $V_{OVDET(S)}$ + 1.0 V is applied to the SENSE pin after V_{SENSE} reaches the release voltage once, until V_{UV} or V_{OV} reaches 50% of V_{DD}.

*6. $V_{UVREL(S)}$: Set undervoltage release voltage value, $V_{OVREL(S)}$: Set overvoltage release voltage value
The time period from when the pulse voltage of $V_{UVREL(S)}$ − 1.0 V → $V_{UVREL(S)}$ + 1.0 V or $V_{OVREL(S)}$ + 1.0 V → $V_{OVREL(S)}$ − 1.0 V is applied to the SENSE pin to when V_{UV} or V_{OV} reaches 50% of V_{DD}.

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Rev.1.2_00   **S-191L/191NxxxxA Series**

2. Supply voltage divider block

Table 14

(Ta = −40°C to +125°C unless otherwise specified)

Item	Symbol	Condition		Min.	Typ.	Max.	Unit	Test Circuit
Input votage	V_{DD}	$V_{DD} \geq V_{SENSE} - 2.0$ V		3.0	–	36.0	V	–
SENSE pin voltage	V_{SENSE}	–		5.0	–	36.0	V	–
Output voltage of supply voltage divider block[*1]	V_{PMOUT}	3.0 V ≤ V_{DD} ≤ 18.0 V, 5.0 V ≤ V_{SENSE} ≤ 18.0 V, −10 μA ≤ I_{PMOUT} ≤ 10 μA	V_{SENSE}/6 output product	$V_{PMOUT(S)}$ × 0.980	V_{SENSE}/6	$V_{PMOUT(S)}$ × 1.020	V	4
			V_{SENSE}/8 output product	$V_{PMOUT(S)}$ × 0.975	V_{SENSE}/8	$V_{PMOUT(S)}$ × 1.025	V	4
			V_{SENSE}/12 output product	$V_{PMOUT(S)}$ × 0.970	V_{SENSE}/12	$V_{PMOUT(S)}$ × 1.030	V	4
		3.0 V ≤ V_{DD} ≤ 18.0 V, 5.0 V ≤ V_{SENSE} ≤ 18.0 V, −3 μA ≤ I_{PMOUT} ≤ 3 μA	V_{SENSE}/14 output product	$V_{PMOUT(S)}$ × 0.966	V_{SENSE}/14	$V_{PMOUT(S)}$ × 1.034	V	4
Load current	I_{PMOUT}	V_{SENSE}/6 output product, V_{SENSE}/8 output product, V_{SENSE}/12 output product		−10	–	10	μA	4
		V_{SENSE}/14 output product		−3	–	3	μA	4
Output impedance	R_{PS}	3.0 V ≤ V_{DD} ≤ 18.0 V, 5.0 V ≤ V_{SENSE} ≤ 18.0 V		–	–	1000	Ω	4
Set-up time[*2]	t_{PU}	V_{DD} = 18.0 V, V_{SENSE} = 18.0 V, C_{PM} = 0.22 μF, no load, t_r = 1.0 μs		–	15	30	ms	5
PMEN pin input voltage "H"	V_{PSH}	V_{DD} = 18.0 V, determined by V_{PMOUT} output level		1.3	–	–	V	6
PMEN pin input voltage "L"	V_{PSL}	V_{DD} = 18.0 V, determined by V_{PMOUT} output level		–	–	0.3	V	6
PMEN pin input current "H"	I_{PSH}	V_{DD} = 18.0 V, V_{PMEN} = V_{DD}		0.00	–	0.50	μA	6
PMEN pin input current "L"	I_{PSL}	V_{DD} = 18.0 V, V_{PMEN} = 0 V		−0.1	–	0.1	μA	6
SENSE pin resistance during operation of supply voltage divider block	$R_{PMSENSE}$	V_{PMEN} = V_{DD}		5.8	–	140	MΩ	7
Discharge shunt resistance during power-off	R_{PLOW}	V_{DD} = 13.5 V, V_{PMEN} = 0 V, V_{PMOUT} = 0.1 V		–	2.8	–	kΩ	8

*1. V_{PMOUT}: Actual output voltage value of supply voltage divider block,
$V_{PMOUT(S)}$: Set output voltage value of supply voltage divider block
*2. Set-up time shows the time period from when the input voltage reaches 50% until the output voltage of supply voltage divider block rises to 99%, when the PMEN pin is set to ON (t_r = 1.0 μs).

3. Overall

Table 15

(Ta = −40°C to +125°C unless otherwise specified)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit	Test Circuit
Current consumption	I_{SS1}	During supply voltage divided output stops, V_{DD} = 13.5 V, V_{SENSE} = 13.5 V, V_{PMEN} = 0 V	–	0.9	3.2	μA	7
	I_{SSP1}	During supply voltage divided output operates, V_{DD} = 13.5 V, V_{SENSE} = 13.5 V, V_{PMEN} = V_{DD}, no load	–	1.3	5.6	μA	7

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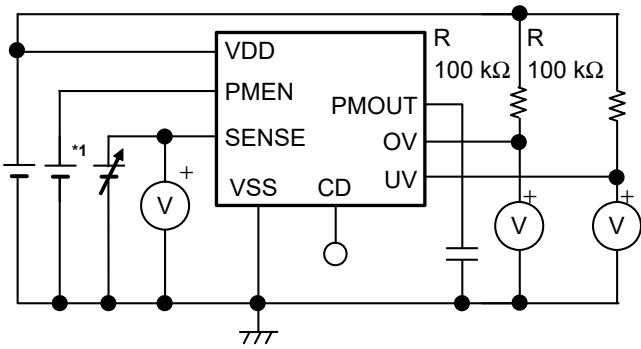
■ Test Circuits

*1. Set to ON

Figure 5   Test Circuit 1
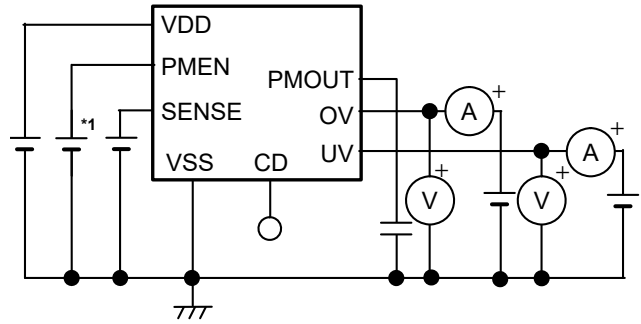
*1. Set to ON

Figure 6   Test Circuit 2
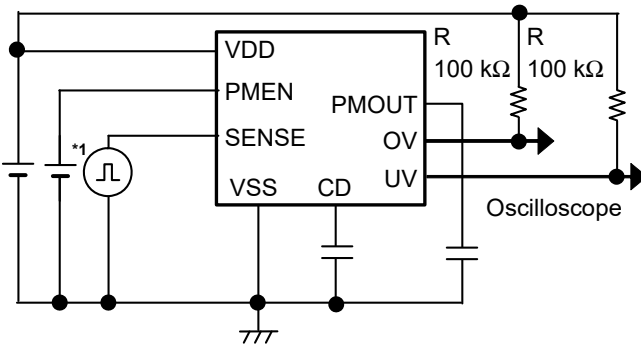
*1. Set to ON

Figure 7   Test Circuit 3
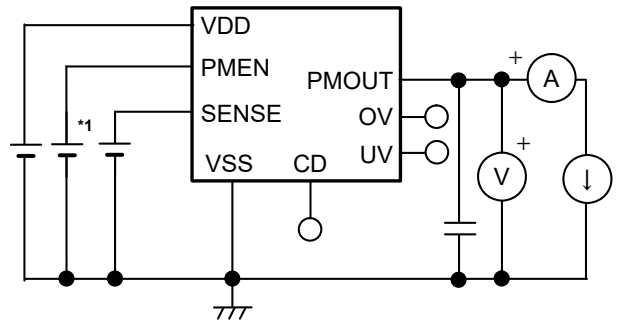
*1. Set to ON

Figure 8   Test Circuit 4
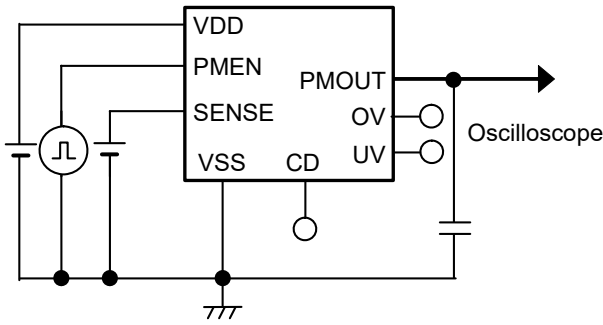
Figure 9   Test Circuit 5
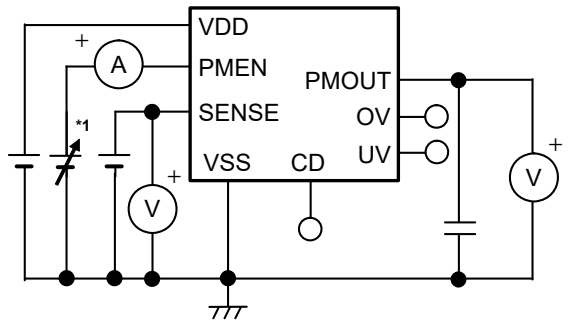
*1. Set to ON or OFF

Figure 10   Test Circuit 6
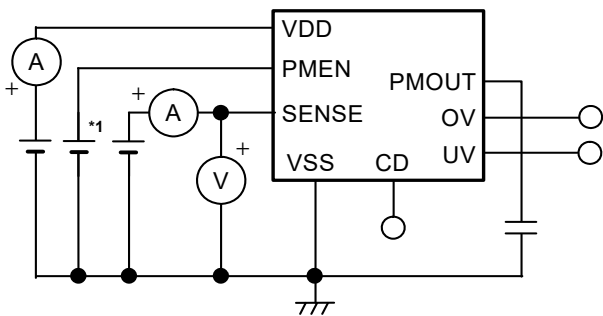
*1. Set to ON or OFF

Figure 11   Test Circuit 7
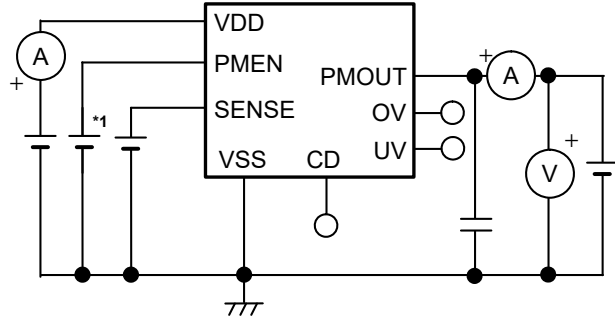
*1. Set to OFF

Figure 12   Test Circuit 8

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■ Standard Circuit
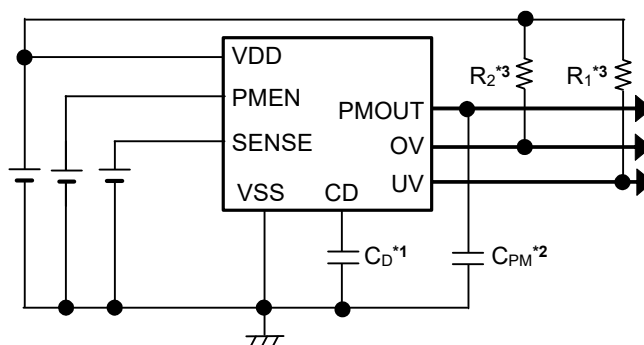
*1. C_D is a release delay time adjustment capacitor. The C_D should be connected directly to the CD pin and the VSS pin.

*2. C_{PM} is a capacitor for stabilizing the output. The C_{PM} should be connected directly to the PMOUT pin and the VSS pin.

*3. R_1, R_2 are the external pull-up resistors for the reset output pin.

Figure 13

Caution   The above connection diagram and constants will not guarantee successful operation. Perform thorough evaluation including the temperature characteristics with an actual application to set the constants.

■ Condition of Application

Release delay time adjustment capacitor (C_D): A ceramic capacitor with capacitance of 1.0 nF or more is recommended.
Supply voltage divider block output capacitor (C_{PM}):   A ceramic capacitor with capacitance of 0.1 μF to 0.22 μF is recommended.

Caution   Generally, in a supply voltage divider, an oscillation may occur depending on the selection of the external parts. Perform thorough evaluation including the temperature characteristics with an actual application using the above capacitors to confirm no oscillation occurs.

■ Selection of Release Delay Time Adjustment Capacitor (C_D)

In this IC, the release delay time adjustment capacitor (C_D) is necessary between the CD pin and the VSS pin to adjust the release delay time (t_{DELAY}) of the detector. Refer to "**1. 4   Delay circuit**" in "**■ Operation**" for details.

Caution   Perform thorough evaluation including the temperature characteristics with an actual application to select C_D.

■ Selection of Supply Voltage Divider Block Output Capacitor (C_{PM})

This IC requires C_{PM} between the PMOUT pin and the VSS pin for phase compensation.
The operation is stabilized by a ceramic capacitor with capacitance of 0.1 μF to 0.22 μF. When using an OS capacitor, a tantalum capacitor or an aluminum electrolytic capacitor, the capacitance also must be 0.1 μF to 0.22 μF. However, an oscillation may occur depending on the equivalent series resistance (ESR).

Caution   Perform thorough evaluation including the temperature characteristics with an actual application to select C_{PM}.

■ Explanation of Terms

1. Detector block

1. 1 Detection voltage (V_{UVDET}, V_{OVDET})

The detection voltage is a SENSE pin voltage at which the output voltage in **Figure 18** turns to "L". The detection voltage varies slightly among products of the same specification. The variation of detection voltage between the specified minimum and the maximum is called the detection voltage range (Refer to "**Figure 14   Overvoltage Detection Voltage**", "**Figure 16   Undervoltage Detection Voltage**").

Table 16

Detection Operation	Detection Voltage	Output Voltage	Detection Voltage Range
Undervoltage detection	V_{UVDET}	V_{UV} = "H" → "L"	V_{UVDET} min. to V_{UVDET} max.
Overvoltage detection	V_{OVDET}	V_{OV} = "H" → "L"	V_{OVDET} min. to V_{OVDET} max.

Example: In V_{UVDET} = 4.0 V product, the detection voltage is at any point in the range of 3.940 V ≤ V_{UVDET} ≤ 4.060 V. This means that some V_{UVDET} = 4.0 V product has V_{UVDET} = 3.940 V and some has V_{UVDET} = 4.060 V.

1. 2 Release voltage (V_{UVREL}, V_{OVREL})

The release voltage is a SENSE pin voltage at which the output voltage in **Figure 18** turns to "H". The release voltage varies slightly among products of the same specification. The variation of release voltage between the specified minimum and the maximum is called the release voltage range (Refer to "**Figure 15   Overvoltage Release Voltage**", "**Figure 17   Undervoltage Release Voltage**").
The release voltage becomes the value differs from the detection voltage within the range shown below.

- M / Q type: 4% to 6% (5% typ.)
- N / R type: 9% to 11% (10% typ.)

Table 17

Detection Operation	Release Voltage	Output Voltage	Release Voltage Range
Undervoltage detection	V_{UVREL}	V_{UV} = "L" → "H"	V_{UVREL} min. to V_{UVREL} max.
Overvoltage detection	V_{OVREL}	V_{OV} = "L" → "H"	V_{OVREL} min. to V_{OVREL} max.

Example: For N / R type, V_{UVDET} = 4.0 V product, the release voltage is at any point in the range of 4.294 V ≤ V_{UVREL} ≤ 4.507 V despite V_{UVREL} = 4.400 V typ. This means that some N / R type, V_{UVDET} = 4.0 V product has V_{UVREL} = 4.294 V and some has V_{UVREL} = 4.507 V.

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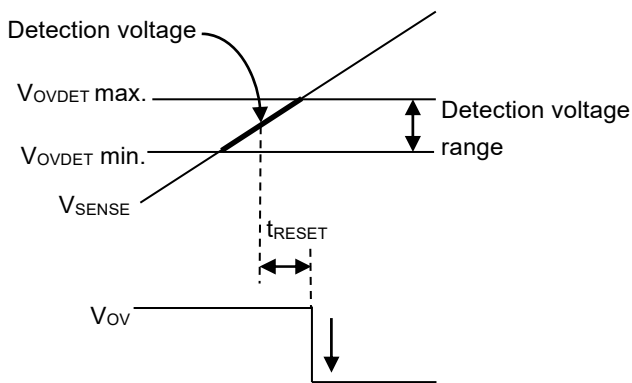
Figure 14   Overvoltage Detection Voltage
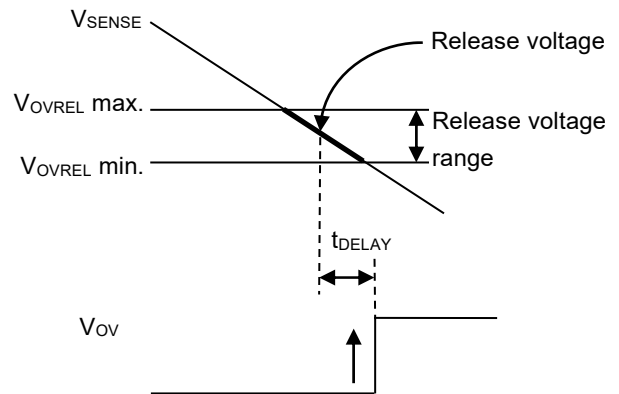
Figure 15   Overvoltage Release Voltage
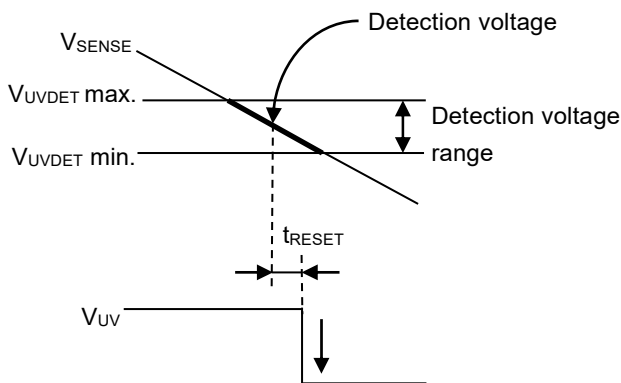
Figure 16   Undervoltage Detection Voltage
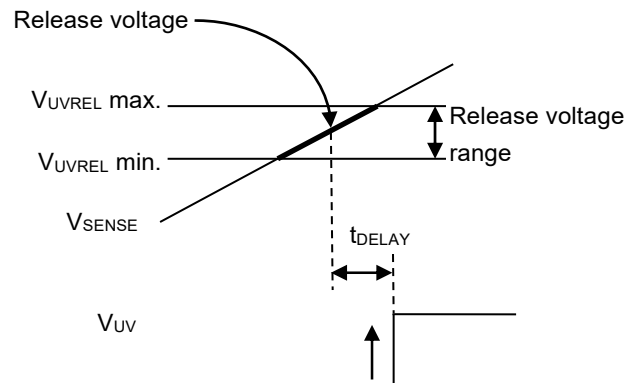
Figure 17   Undervoltage Release Voltage
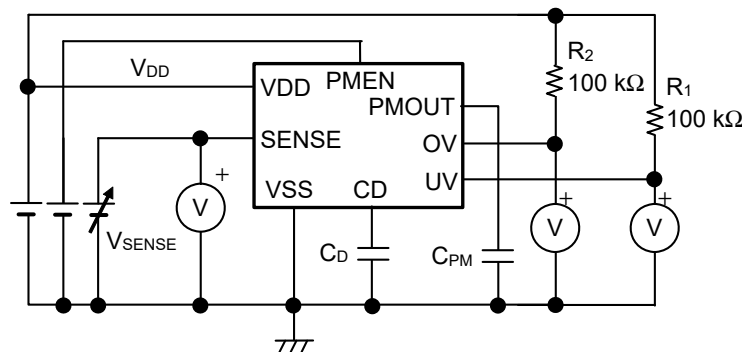
Figure 18   Test Circuit of Detection Voltage and Release Voltage

1. 3   Hysteresis width (V_{UVHYS}, V_{OVHYS})

The hysteresis width is the voltage difference between the detection voltage and the release voltage. Setting the hysteresis width between the detection voltage and the release voltage, prevents malfunction caused by noise on the input voltage.

- Undervoltage hysteresis width (V_{UVHYS}): V_{UVREL} – V_{UVDET}
- Overvoltage hysteresis width (V_{OVHYS}): V_{OVDET} – V_{OVREL}

1. 4   Feed-through current

The feed-through current is a current that flows instantaneously to the VDD pin at the time of detection and release of a voltage detector.

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2. Supply voltage divider block

2.1 Supply voltage divided output

The supply voltage divided output is a function that divides the SENSE pin voltage (V_{SENSE}) into $V_{SENSE}/6$, $V_{SENSE}/8$, $V_{SENSE}/12$ or $V_{SENSE}/14$ and outputs the voltage.

For example, a microcontroller can monitor a battery voltage by inputting the output voltage of supply voltage divider block (V_{PMOUT}) to the microcontroller A/D converter.

2.2 Output voltage of supply voltage divider block (V_{PMOUT})

This is the voltage of the divided V_{SENSE}. The following voltages are the outputs.

- S-191L Series L / M / N type: $V_{SENSE}/6$
- S-191L Series P / Q / R type: $V_{SENSE}/8$
- S-191N Series L / M / N type: $V_{SENSE}/12$
- S-191N Series P / Q / R type: $V_{SENSE}/14$

This voltage is the output in accuracy range of between ±2.0% and ±3.4%[1] when the power supply voltage, V_{SENSE}, temperature and load current satisfy a certain condition[1].

[1]. Differs depending on the product type.

Example: For S-191L Series L / M / N type, V_{SENSE} = 15.0 V, the output voltage of supply voltage divider block is at any point in the range of 2.450 V ≤ V_{PMOUT} ≤ 2.550 V.
This means that some S-191L Series L / M / N type has V_{PMOUT} = 2.450 V and some has V_{PMOUT} = 2.550 V.

Caution **If the certain condition is not satisfied, the output voltage may exceed the accuracy range.**
Refer to Table 14 of "■ Electrical Characteristics" for details.

2.3 Output impedance (R_{PS})

This is the supply voltage divider block impedance. It shows how much output offset voltage changes when the load current changes.

For example, the output impedance can be used in sampling rate calculation as signal source impedance when V_{PMOUT} from the PMOUT pin is input to the A/D converter as a microcontroller input signal.

2.4 Set-up time (t_{PU})

This is the time from when the supply voltage divided output is operated until V_{PMOUT} stabilizes.

2.5 Discharge shunt resistance during power-off (R_{PLOW})

This is the ON resistance of the N-channel transistor built into the supply voltage divider block.
When the supply voltage divided output is stopped, V_{PMOUT} is set to the V_{SS} level by the built-in N-channel transistor.

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■ Operation

1. Detector block

Figure 19 and **Figure 21** show that the UV and OV pins being pulled up by resistors (R_1, R_2) is an example of basic detector block operation.

1. 1 S-191L/191N Series L / P type

(1) Undervoltage detection status to release status (undervoltage release status)
When the SENSE pin voltage (V_{SENSE}) exceeds the undervoltage release voltage ($V_{UVREL} = V_{UVDET}$), the UV pin voltage output becomes "H" after release delay time (t_{DELAY}). At this time, the OV pin output stays at "H".
(2) Release status to overvoltage detection status
V_{SENSE} rises, and when it exceeds the overvoltage detection voltage (V_{OVDET}), the OV pin output becomes "L" after detection response time (t_{RESET}). At this time, the UV pin stays at "H".
(3) Overvoltage detection status to release status (overvoltage release status)
V_{SENSE} drops, and when it goes below the overvoltage release voltage ($V_{OVREL} = V_{OVDET}$), the OV pin output changes to "H" after t_{DELAY}. At this time, the UV pin output stays at "H".
(4) Release status to undervoltage detection status
V_{SENSE} drops, and when it goes below the undervoltage detection voltage (V_{UVDET}), the UV pin output becomes "L" after t_{RESET} and changes to undervoltage detection status. At this time, the OV pin output stays at "H".
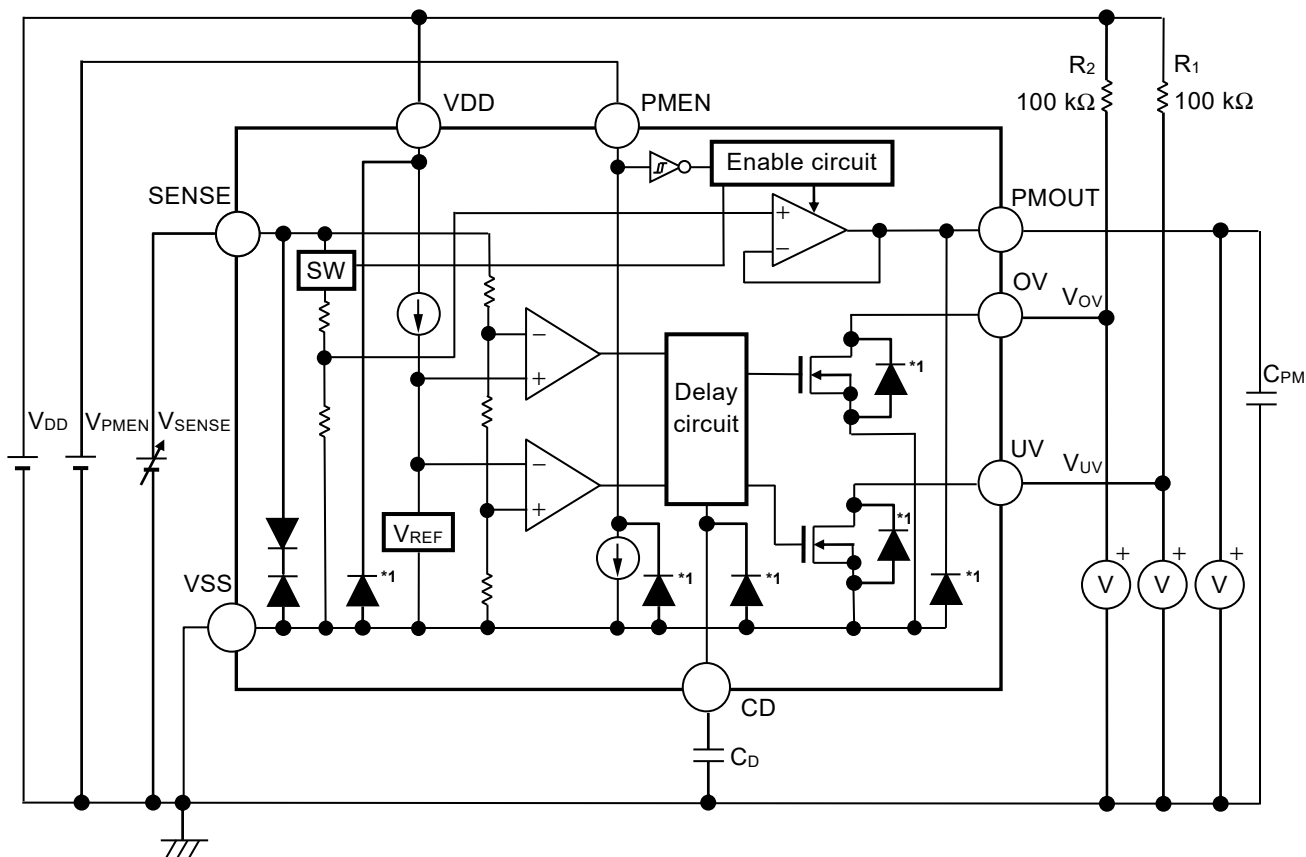
*1. Parasitic diode

Figure 19   Operation of S-191L/191N Series L / P type
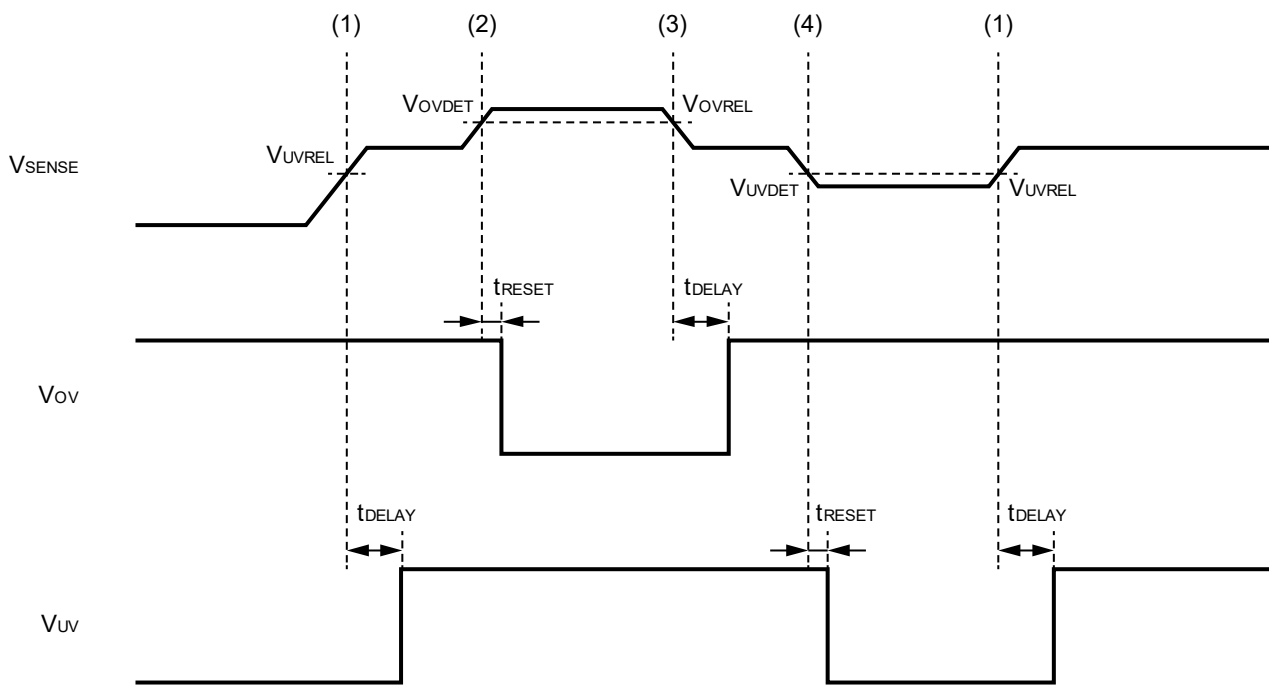
Figure 20   Timing Chart of S-191L/191N Series L / P Type

1. 2 S-191L/191N Series M / N / Q / R type

(1) Undervoltage detection status to release status (undervoltage release status)

When the SENSE pin voltage (V_{SENSE}) exceeds the undervoltage release voltage ($V_{UVREL} = V_{UVDET} + V_{UVHYS}$), the UV pin voltage output becomes "H" after release delay time (t_{DELAY}). At this time, the OV pin output stays at "H".

(2) Release status to overvoltage detection status

V_{SENSE} rises, and when it exceeds the overvoltage detection voltage (V_{OVDET}), the OV pin output becomes "L" after detection response time (t_{RESET}). At this time, the UV pin stays at "H".

(3) Overvoltage detection status to release status (overvoltage release status)

V_{SENSE} drops, and when it goes below the overvoltage release voltage ($V_{OVREL} = V_{OVDET} - V_{OVHYS}$), the OV pin output changes to "H" after t_{DELAY}. At this time, the UV pin output stays at "H".

(4) Release status to undervoltage detection status

V_{SENSE} drops, and when it goes below the undervoltage detection voltage (V_{UVDET}), the UV pin output becomes "L" after t_{RESET} and changes to undervoltage detection status. At this time, the OV pin output stays at "H".
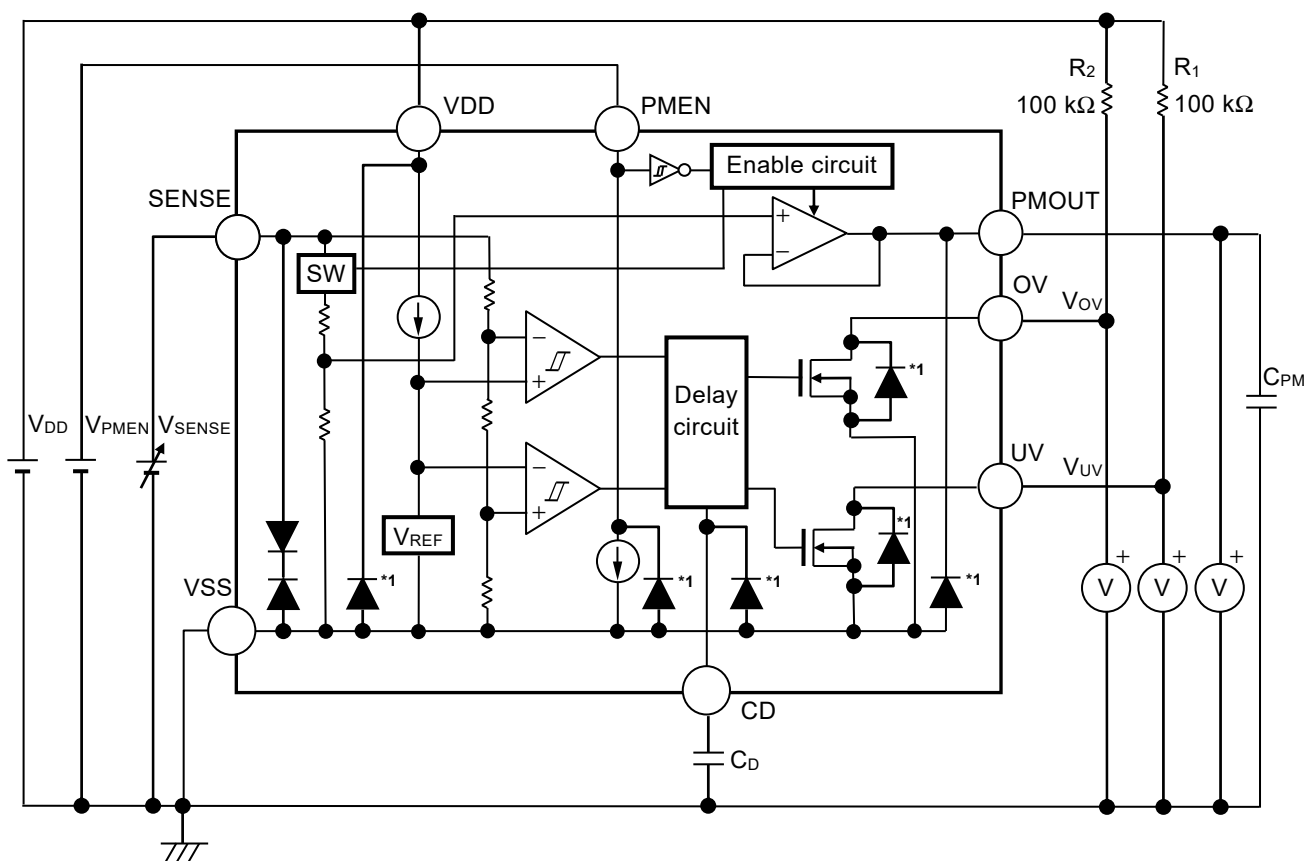
*1. Parasitic diode

Figure 21   Operation of S-191L/191N Series M / N / Q / R type
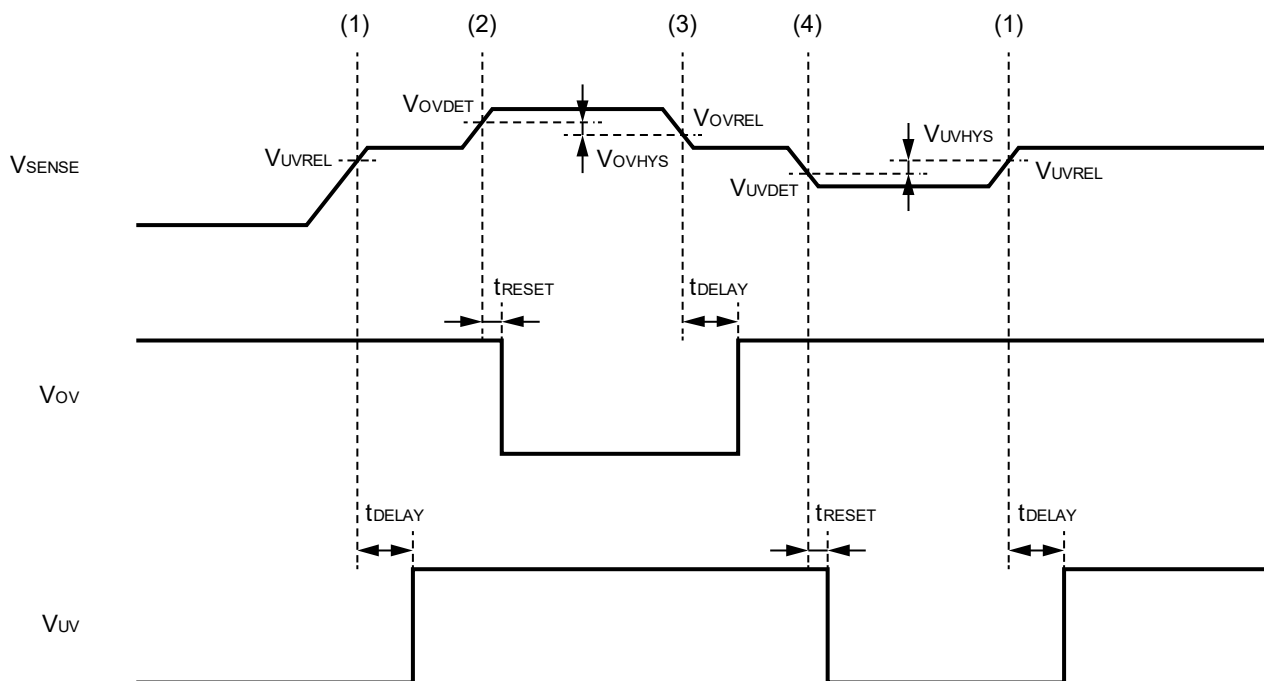
Figure 22 Timing Chart of S-191L/191N Series M / N / Q / R Type

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1. 3   SENSE pin

The SENSE pin is the input pin for the detection voltage. The power supply VDD pin and SENSE pin, for voltage detection, are divided. Therefore, as long as a voltage is supplied to the VDD pin, the reset signal will be held even if the input voltage to the SENSE pin drops below the minimum operation voltage. Also, the SENSE pin of this IC has a built-in reverse connection protection circuit. Even when the SENSE pin voltage is less than the VSS pin voltage, the voltage flowing from the VSS pin to the SENSE pin is reduced to 0.05 mA typ.

1. 3. 1   Error when detection voltage is set externally

The undervoltage detection voltage and the overvoltage detection voltage can be set externally by connecting a node that was resistance-divided by the resistor (R_A) and the resistor (R_B) to the SENSE pin as shown in **Figure 23**.

For conventional products without the SENSE pin, external resistor cannot be too large since the resistance-divided node must be connected to the VDD pin. This is because a feed-through current will flow through the VDD pin when it goes from detection to release, and if external resistor is large, problems such as oscillation or larger error in the hysteresis width may occur.

In this IC, R_A and R_B in **Figure 23** are easily made larger since the resistance-divided node can be connected to the SENSE pin through which no feed-through current flows. However, be careful of error in the current flowing through the internal resistance (R_{SENSE}) that will occur.

Although R_{SENSE}[1] in this IC is large to make the error small, R_A and R_B should be selected such that the error is within the allowable limits.

Please note that the supply voltage divided output is a function to divide and output the SENSE pin voltage so when the detection voltage is set externally, care is required as the supply voltage divider block output voltage will change.

[1].   During supply voltage divided output stops: 6.8 MΩ min.
During supply voltage divided output operates: 5.8 MΩ min.

1. 3. 2 Selection of R_A and R_B

In **Figure 23**, the relation between the external setting undervoltage detection voltage (V_{DUX}) or the overvoltage detection voltage (V_{DOX}) and the actual detection voltage (V_{UVDET}, V_{OVDET}) is ideally calculated by the equation below.

$$V_{DUX} = V_{UVDET} \times \left(1 + \frac{R_A}{R_B}\right) \cdots\cdots\cdots\cdots\cdots\cdots\cdots(1)$$

$$V_{DOX} = V_{OVDET} \times \left(1 + \frac{R_A}{R_B}\right) \cdots\cdots\cdots\cdots\cdots\cdots\cdots(1)$$

However, in reality there is an error in the current flowing through R_{SENSE}.
When considering this error, the relation between V_{DUX}, V_{DOX} and V_{OVDET} is calculated as follows.

$$
\begin{aligned}
V_{DUX} &= V_{UVDET} \times \left(1 + \frac{R_A}{R_B \parallel R_{SENSE}}\right) \\
&= V_{UVDET} \times \left(1 + \frac{R_A}{\frac{R_B \times R_{SENSE}}{R_B + R_{SENSE}}}\right) \\
&= V_{UVDET} \times \left(1 + \frac{R_A}{R_B}\right) + \frac{R_A}{R_{SENSE}} \times V_{UVET} \cdots\cdots\cdots(2)
\end{aligned}
$$

$$V_{DOX} = V_{OVDET} \times \left(1 + \frac{R_A}{R_B}\right) + \frac{R_A}{R_{SENSE}} \times V_{OVET} \cdots\cdots\cdots(2)$$

By using equations (1) and (2), the error is calculated as $V_{UVDET} \times \dfrac{R_A}{R_{SENSE}}$, $V_{OVDET} \times \dfrac{R_A}{R_{SENSE}}$.

The error rate is calculated as follows by dividing the error by the right-hand side of equation (1).

$$\frac{R_A \times R_B}{R_{SENSE} \times (R_A + R_B)} \times 100\ [\%] = \frac{R_A \parallel R_B}{R_{SENSE}} \times 100\ [\%] \quad \cdots(3)$$

As seen in equation (3), the smaller the resistance values of R_A and R_B compared to R_{SENSE}, the smaller the error rate becomes.

Also, the relation between the external setting undervoltage hysteresis width (V_{HUX}) or the overvoltage hysteresis width (V_{HOX}) and the hysteresis width (V_{UVHYS}, V_{OVHYS}) is calculated by equation below. Error due to R_{SENSE} also occurs to the relation in a similar way to the detection voltage.

$$V_{HUX} = V_{UVHYS} \times \left(1 + \frac{R_A}{R_B}\right) \cdots\cdots\cdots\cdots\cdots\cdots\cdots(4)$$

$$V_{HOX} = V_{OVHYS} \times \left(1 + \frac{R_A}{R_B}\right) \cdots\cdots\cdots\cdots\cdots\cdots\cdots(4)$$
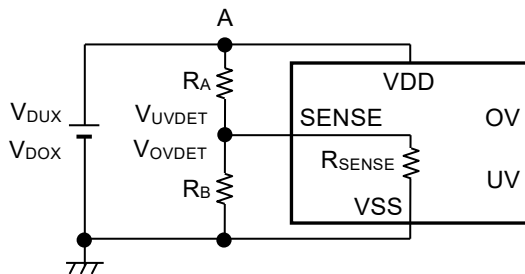
Figure 23   Detection Voltage External Setting Circuit

Caution   If R_A and R_B are large, the SENSE pin input impedance becomes higher and may cause a malfunction due to noise. In this case, connect a capacitor between the SENSE pin and the VSS pin.

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1. 4 Delay circuit

The delay circuit comes with a function for adjusting the release delay time (t_{DELAY}) from when the SENSE pin voltage (V_{SENSE}) enters the state in **Table 18** and until the output pin inverts.

Table 18

Release operation	Status	Output Pin
Undervoltage release	Undervoltage release voltage ($V_{UVREL} = V_{UVDET} + V_{UVHYS}$) or more	UV pin
Overvoltage release	Overvoltage release voltage ($V_{OVREL} = V_{OVDET} - V_{OVHYS}$) or lower	OV pin

t_{DELAY} is determined by the delay coefficient, the release delay time adjustment capacitor (C_D) and the release delay time when the CD pin is open (t_{DELAY0}). They are calculated by the equations below.

t_{DELAY} [ms] = Delay coefficient $\times$ C_D [nF] + t_{DELAY0} [ms]

Table 19

Operation	Delay Coefficient		
Temperature	Min.	Typ.	Max.
Ta = +125°C	2.65	3.03	3.41
Ta = +105°C	2.71	3.05	3.35
Ta = +25°C	2.92	3.06	3.14
Ta = −40°C	2.65	3.09	3.41

Table 20

Operation	Release Delay Time when CD Pin is Open (t_{DELAY0})		
Temperature	Min.	Typ.	Max.
Ta = +125°C	0.05	0.09	0.17
Ta = +105°C	0.05	0.10	0.17
Ta = +25°C	0.06	0.11	0.19
Ta = −40°C	0.06	0.13	0.25

Caution 1. **Mounted board layout should be made in such a way that no current flows into or flows from the CD pin since the impedance of the CD pin is high, otherwise correct delay time cannot be provided.**

2. **There is no limit for the capacitance of C_D as long as the leakage current of the capacitor can be ignored against the built-in constant current value (approximately 160 nA). The leakage current may cause error in delay time. When the leakage current is larger than the built-in constant current, no detect or release takes place.**

3. **The above equations will not guarantee successful operation. Determine the capacitance of C_D through thorough evaluation including temperature characteristics in the actual usage conditions.**

2. Supply voltage divider block

2. 1 Basic operation

Figure 24 shows the block diagram of the supply voltage divider block to describe basic operation.

Reference voltage (V_{refpm}) is generated by dividing the SENSE pin voltage (V_{SENSE}) using the dividing resistance (R_{pm1} and R_{pm2}). Since the buffer amplifier constitutes a voltage follower, it can perform the feedback control so that the output voltage of supply voltage divider block (V_{PMOUT}) and V_{refpm} are the same. Low output impedance is realized by the buffer amplifier, while outputting V_{PMOUT} according to V_{SENSE}.

When "L" is input to the PMEN pin, the current which flows to R_{pm1} and R_{pm2} and the current which flows to the buffer amplifier can be stopped. The buffer amplifier output is pulled down to V_{SS} by the built-in N-channel transistor, and V_{PMOUT} is set to the V_{SS} level.

Figure 24

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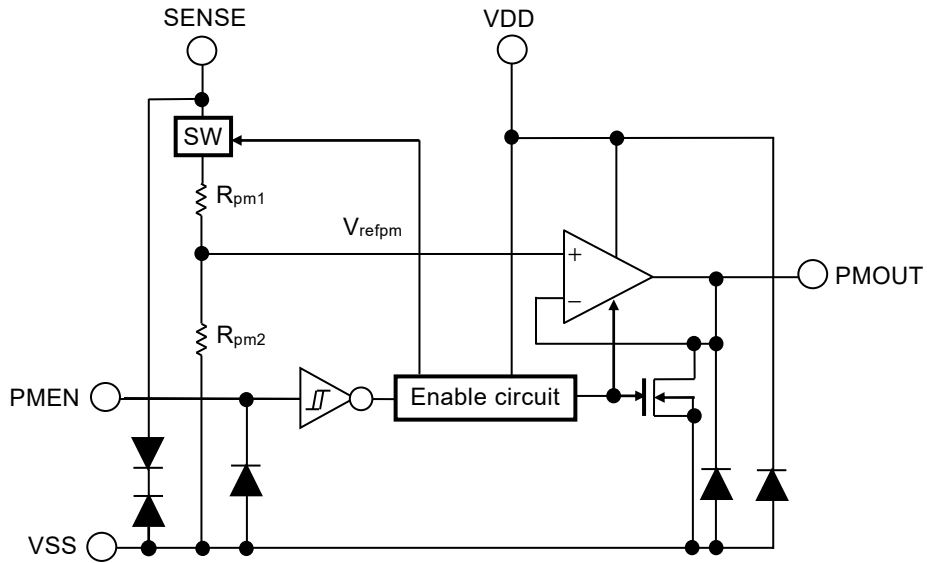
2. 2 PMEN pin

Input to the PMEN pin controls the internal circuit in the supply voltage divided output, and it starts or stops the supply voltage divided output.

When the PMEN pin is set to "L" level, the internal circuit stops operating, reducing current consumption significantly. In addition, the PMEN pin has absolutely no effect on the operation of the detector block.

Note that the current consumption increases when a voltage of 0.8 V to V_{DD} min. − 0.3 V is applied to the PMEN pin. The PMEN pin is configured as shown in **Figure 25**.

Since the PMEN pin is internally pulled down to the VSS pin in the floating status, the PMOUT pin is set to the V_{SS} level. When the PMEN pin is set to "H" level, PMEN pin input current "H" (I_{PSH}) in **Table 14** of "■ **Electrical Characteristics**" flows through the PMEN pin and care is required.

Table 21

Product Type	PMEN Pin	Internal Circuit	PMOUT Pin Output	Current Consumption
L / M / N / P / Q / R	"H": ON	Operate	Constant value[*1]	I_{SSP1}
L / M / N / P / Q / R	"L": OFF	Stop	Pulled down to V_{SS}[*2]	I_{SS1}

*1. The constant value is output due to the operation based on the set output voltage value of supply voltage divider block.

*2. The buffer amplifier output is pulled down to V_{SS} by the built-in N-channel transistor, and PMOUT pin output is set to the V_{SS} level due to resistance (R_{LOW} = 2.8 kΩ typ.) of the discharge shunt circuit and a load.
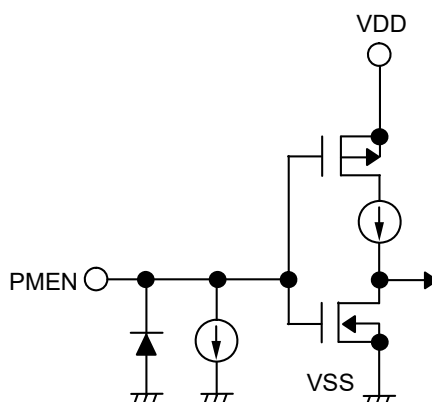
Figure 25

2. 3   PMEN pin voltage and output voltage of supply voltage divider block (V_{PMOUT})

Figure 26 shows the timing chart of the supply voltage divided output.

When "H" is input to the PMEN pin, the supply voltage divided output operates. When the set-up time (t_{PU}) = 50 ms max.[*1] elapses, V_{PMOUT} stabilizes, the SENSE pin voltage (V_{SENSE}) is divided at the set ratio, and the voltage is output to the PMOUT pin.

When "L" is input to the PMEN pin, the supply voltage divided output is stopped. V_{PMOUT} is set to the V_{SS} level by the built-in N-channel transistor.

By repeatedly inputting "H" and "L" to the PMEN pin, it is possible to lower current consumption when the supply voltage divided output is not needed.

*1.   When 5 V $\leq V_{SENSE} \leq$ 18 V, C_{PM} = 0.22 μF, no load
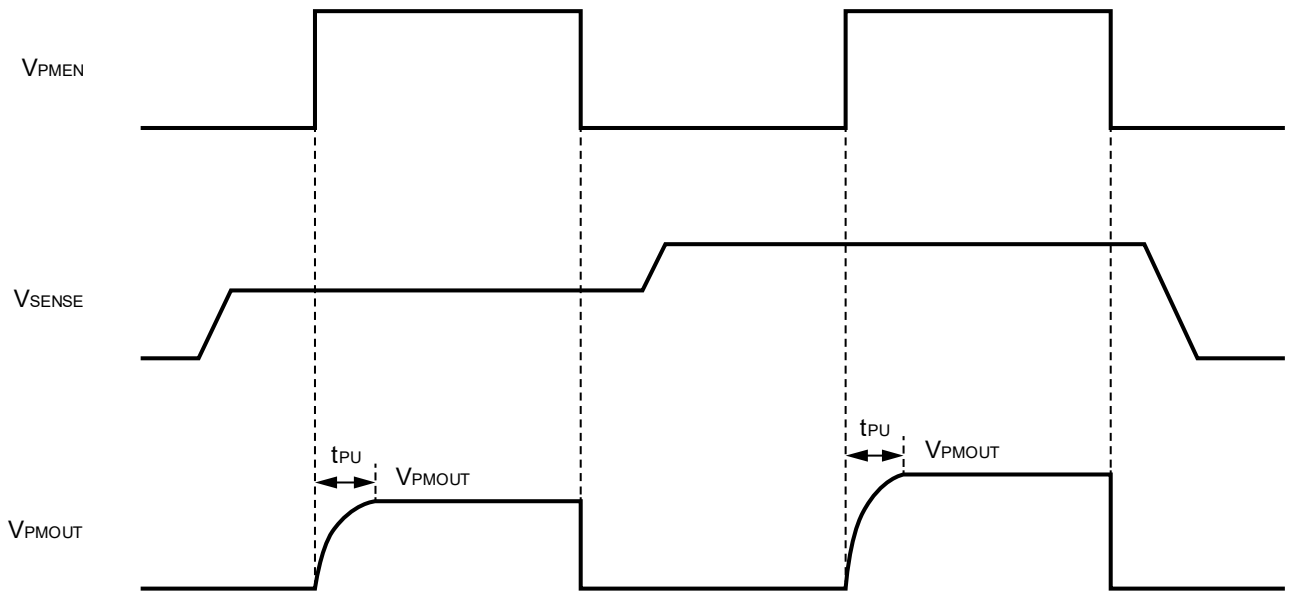
Figure 26

Remark $V_{PMEN} = V_{DD} \leftrightarrow V_{SS}$

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■ Usage Precautions

1.   Power on sequence

Turn on the power in one of the following two procedures.

(1) Order of VDD pin and SENSE pin (Refer to **Figure 27**)
(2) VDD pin and SENSE pin at the same time

When $V_{OVDET} \geq V_{SENSE} \geq V_{UVREL}$ applies, both the overvoltage output voltage (V_{OV}) and the undervoltage output voltage (V_{UV}) become "H", and the detector enters release status.
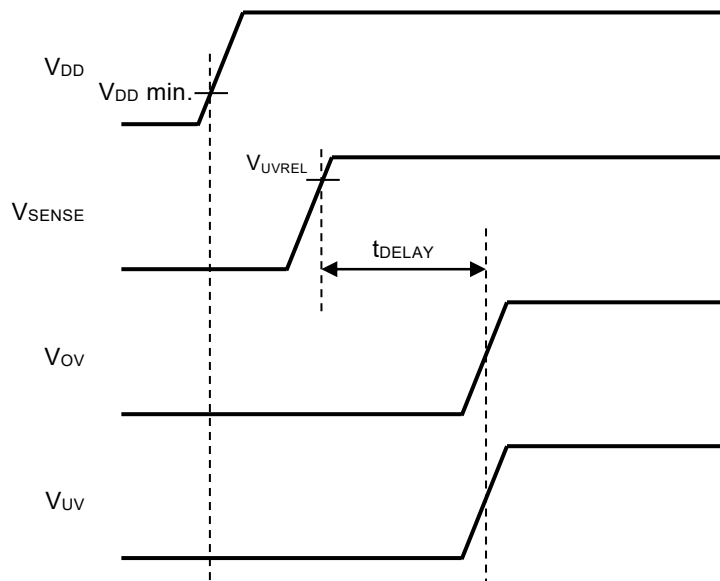
Figure 27

Caution   When the SENSE pin is turned on before the VDD pin, a release may mistakenly occur even if V_{SENSE} is less than V_{UVREL}.

2. SENSE pin voltage glitch (Typical data)

2. 1 Undervoltage detection operation

Figure 28 shows the relation between pulse width and pulse voltage difference (V_{OD}) where the undervoltage release status can be maintained when a pulse equal to or lower than the undervoltage detection voltage (V_{UVDET}) is input to the SENSE pin during undervoltage release status.

$T_j = -40°C$ to $+150°C$
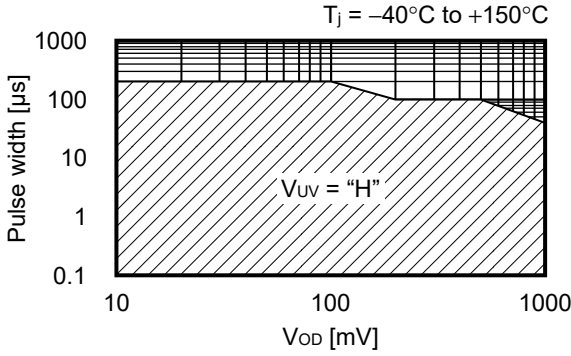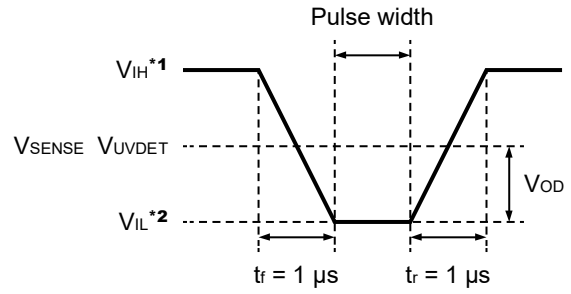
Figure 28

*1. $V_{IH} = 13.5$ V
*2. $V_{IL} = V_{UVDET} - V_{OD}$

Figure 29　SENSE Pin Input Voltage Waveform

Caution　**Figure 28 shows the pulse condition which can maintain the undervoltage release status. If the pulse whose pulse width and V_{OD} are larger than this condition is input to the SENSE pin, the UV pin may change to an undervoltage detection status.**

2. 2 Undervoltage release operation

Figure 30 shows the relation between pulse width and pulse voltage difference (V_{OD}) where the undervoltage detection status can be maintained when a pulse equal to or higher than the undervoltage release voltage (V_{UVREL}) is input to the SENSE pin during undervoltage detection status.

$T_j = -40°C$ to $+150°C$
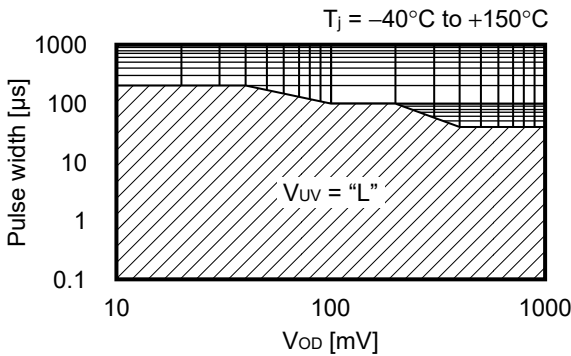
Figure 30

*1. $V_{IH} = V_{UVREL} + V_{OD}$
*2. $V_{IL} = V_{UVDET} - 1.0$ V

Figure 31　SENSE Pin Input Voltage Waveform

Caution　**Figure 30 shows the pulse condition which can maintain the undervoltage detection status. If the pulse whose pulse width and V_{OD} are larger than this condition is input to the SENSE pin, the UV pin may change to an undervoltage release status.**

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AUTOMOTIVE, 125°C OPERATION, 36 V, SUPPLY VOLTAGE DIVIDED OUTPUT, WINDOW VOLTAGE DETECTOR WITH SENSE PIN REVERSE CONNECTION PROTECTION

Rev.1.2_00   **S-191L/191NxxxxA Series**

2. 3 Overvoltage detection operation

Figure 32 shows the relation between pulse width and pulse voltage difference (V_{OD}) where the overvoltage release status can be maintained when a pulse equal to or higher than the overvoltage detection voltage (V_{OVDET}) is input to the SENSE pin during overvoltage release status.
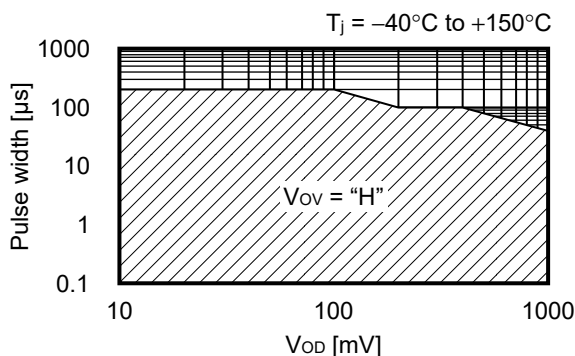
Figure 32
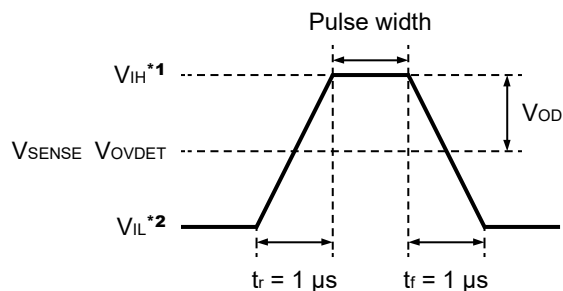
*1. $V_{IH} = V_{OVDET} + V_{OD}$
*2. $V_{IL} = 13.5$ V

Figure 33   SENSE Pin Input Voltage Waveform

Caution   Figure 32 shows the pulse condition which can maintain the overvoltage release status. If the pulse whose pulse width and V_{OD} are larger than this condition is input to the SENSE pin, the OV pin may change to an overvoltage detection status.

2. 4 Overvoltage release operation

Figure 34 shows the relation between pulse width and pulse voltage difference (V_{OD}) where the overvoltage detection status can be maintained when a pulse equal to or lower than the overvoltage release voltage (V_{OVREL}) is input to the SENSE pin during overvoltage detection status.
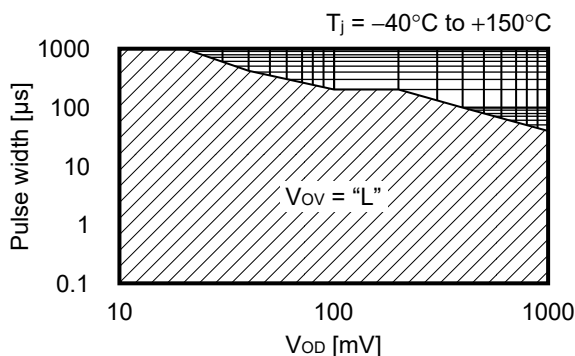
Figure 34
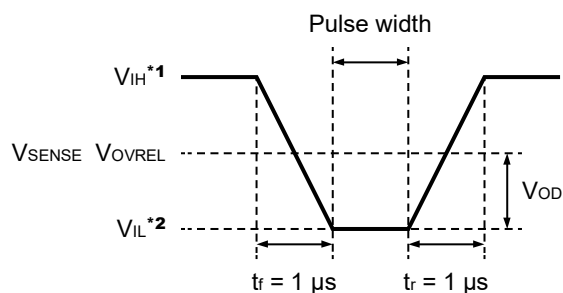
*1. $V_{IH} = V_{OVDET} + 1.0$ V
*2. $V_{IL} = V_{OVREL} - V_{OD}$

Figure 35   SENSE Pin Input Voltage Waveform

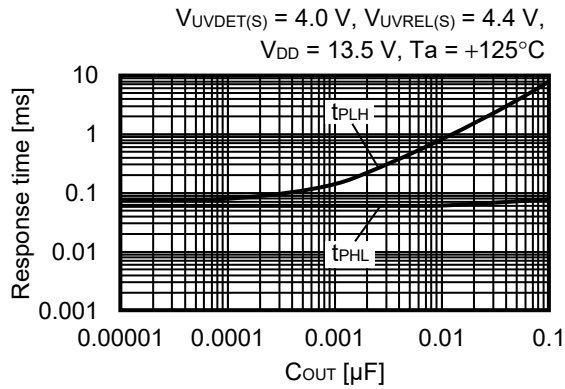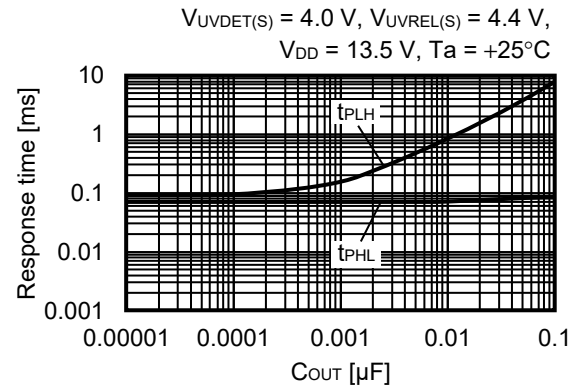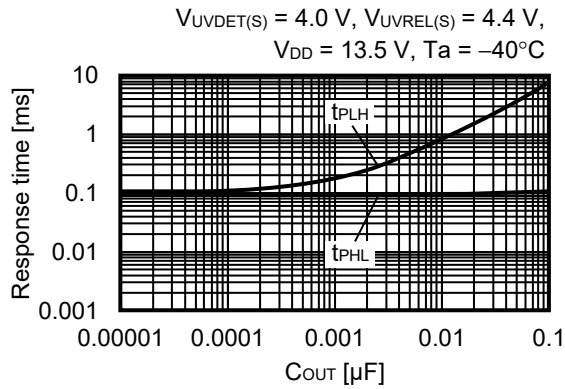**Caution   Figure 34 shows the pulse condition which can maintain the overvoltage detection status. If the pulse whose pulse width and V_{OD} are larger than this condition is input to the SENSE pin, the OV pin may change to an overvoltage release status.**

■ Precautions

- Do not apply an electrostatic discharge to this IC that exceeds the performance ratings of the built-in electrostatic protection circuit.

- Because the SENSE pin has a high impedance, malfunctions may occur due to noise.
  Be careful of wiring adjoining SENSE pin wiring in actual applications.

- In the supply voltage divided output, the values of an overshoot and an undershoot in the output voltage vary depending on the variation factors of input voltage start-up, input voltage fluctuation and load fluctuation etc., or the capacitance of C_{PM} and the value of the equivalent series resistance (ESR), which may cause a problem to the stable operation. Perform thorough evaluation including the temperature characteristics with an actual application to select C_{PM}.

- When designing for mass production using an application circuit described herein, the product deviation and temperature characteristics should be taken into consideration. ABLIC Inc. shall not bear any responsibility for patent infringements related to products using the circuits described herein.

- ABLIC Inc. claims no responsibility for any disputes arising out of or in connection with any infringement by products including this IC of patents owned by a third party.

■ Characteristics (Typical Data)

1. Detector block

1. 1 Detection voltage (V_{UVDET}, V_{OVDET}), Release voltage (V_{UVREL}, V_{OVREL}) vs. Temperature (Ta)

1. 1. 1 Undervoltage detection

$V_{UVDET(S)} = 4.0$ V, $V_{UVREL(S)} = 4.4$ V, $V_{DD} = 13.5$ V

$V_{UVDET(S)} = 10.0$ V, $V_{UVREL(S)} = 11.0$ V, $V_{DD} = 13.5$ V

1. 1. 2 Overvoltage detection

$V_{OVDET(S)} = 16.0$ V, $V_{OVREL(S)} = 14.4$ V, $V_{DD} = 13.5$ V

$V_{OVDET(S)} = 18.0$ V, $V_{OVREL(S)} = 16.2$ V, $V_{DD} = 13.5$ V
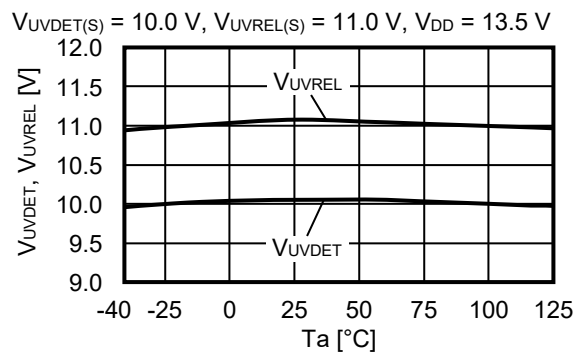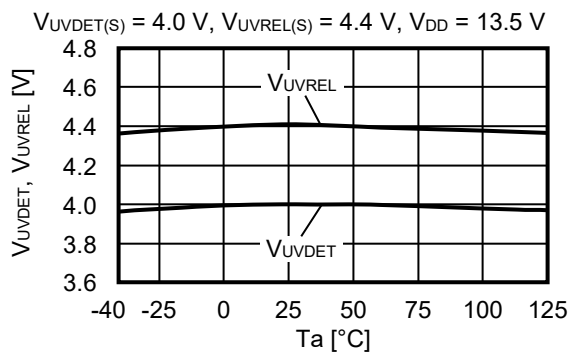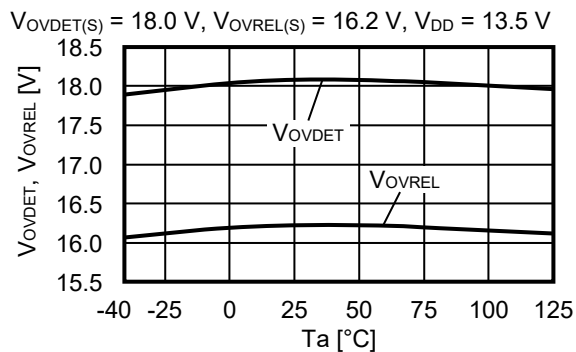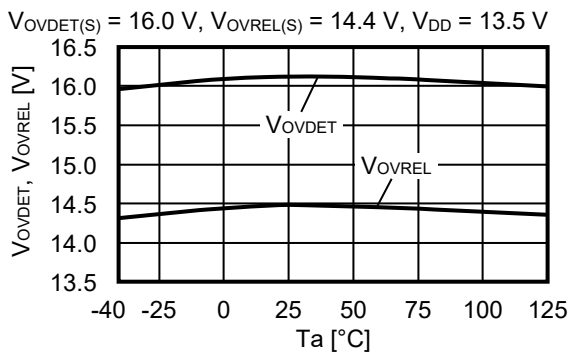
1. 2 Detection voltage (V_{UVDET}, V_{OVDET}), Release voltage (V_{UVREL}, V_{OVREL}) vs. Power supply voltage (V_{DD})

1. 2. 1 Undervoltage detection

$V_{UVDET(S)} = 4.0$ V, $V_{UVREL(S)} = 4.4$ V

$V_{UVDET(S)} = 10.0$ V, $V_{UVREL(S)} = 11.0$ V

1. 2. 2 Overvoltage detection

$V_{OVDET(S)} = 16.0$ V, $V_{OVREL(S)} = 14.4$ V

$V_{OVDET(S)} = 18.0$ V, $V_{OVREL(S)} = 16.2$ V

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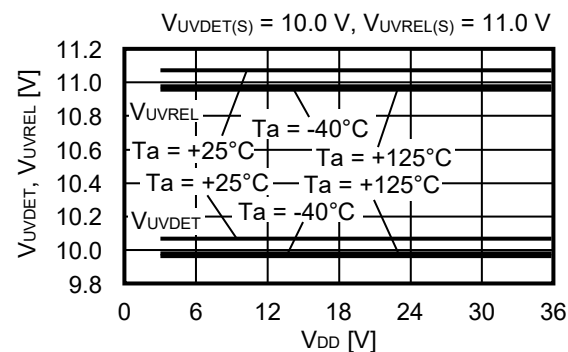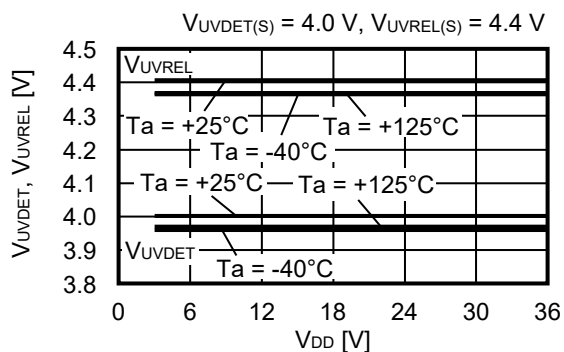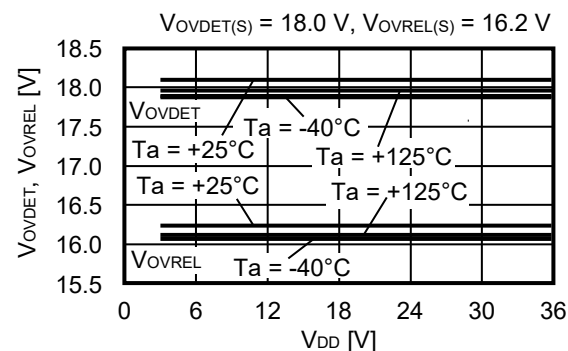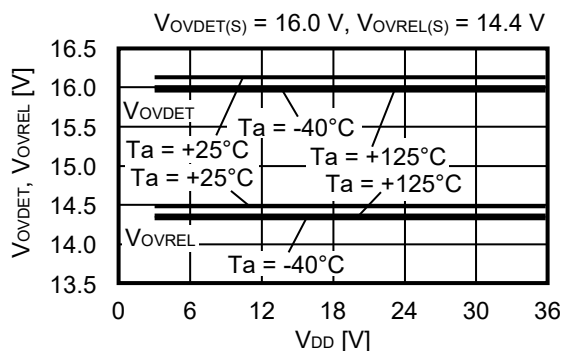
1. 3 Hysteresis width (V$_{UVHYS}$, V$_{OVHYS}$) vs. Temperature (Ta)

1. 3. 1 Undervoltage detection

V$_{UVDET(S)}$ = 4.0 V, V$_{UVREL(S)}$ = 4.4 V, V$_{DD}$ = 13.5 V

V$_{UVDET(S)}$ = 10.0 V, V$_{UVREL(S)}$ = 11.0 V, V$_{DD}$ = 13.5 V

1. 3. 2 Overvoltage detection

V$_{OVDET(S)}$ = 16.0 V, V$_{OVREL(S)}$ = 14.4 V, V$_{DD}$ = 13.5 V

V$_{OVDET(S)}$ = 18.0 V, V$_{OVREL(S)}$ = 16.2 V, V$_{DD}$ = 13.5 V
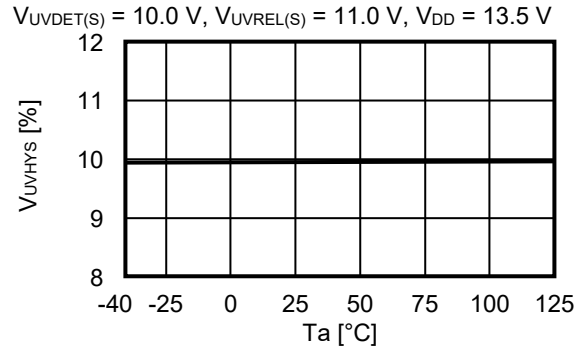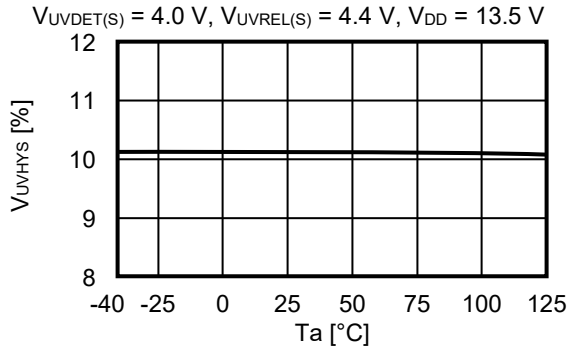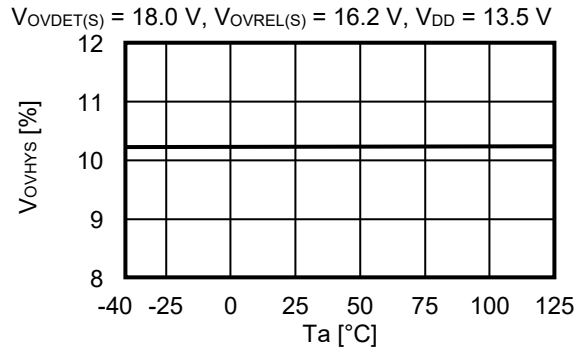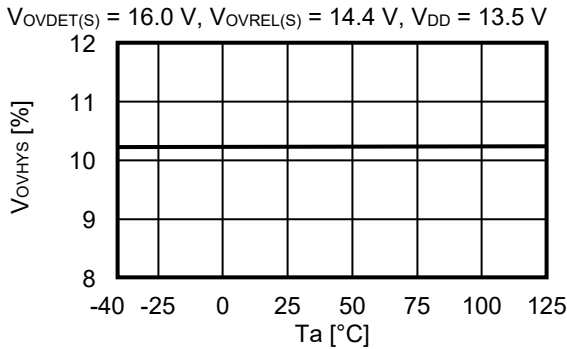
1. 4 Hysteresis width (V$_{UVHYS}$, V$_{OVHYS}$) vs. Power supply voltage (V$_{DD}$)

1. 4. 1 Undervoltage detection

V$_{UVDET(S)}$ = 4.0 V, V$_{UVREL(S)}$ = 4.4 V

V$_{UVDET(S)}$ = 10.0 V, V$_{UVREL(S)}$ = 11.0 V

1. 4. 2 Overvoltage detection

V$_{OVDET(S)}$ = 16.0 V, V$_{OVREL(S)}$ = 14.4 V

V$_{OVDET(S)}$ = 18.0 V, V$_{OVREL(S)}$ = 16.2 V

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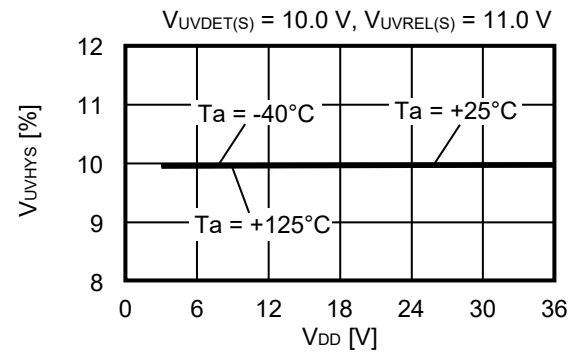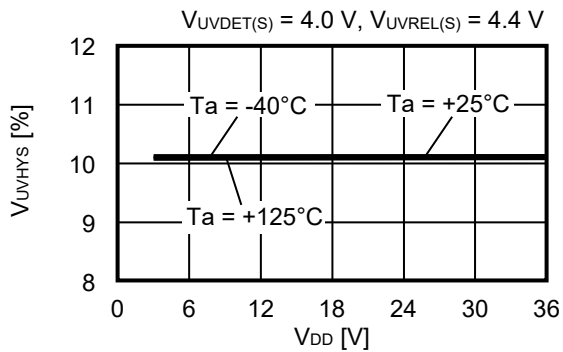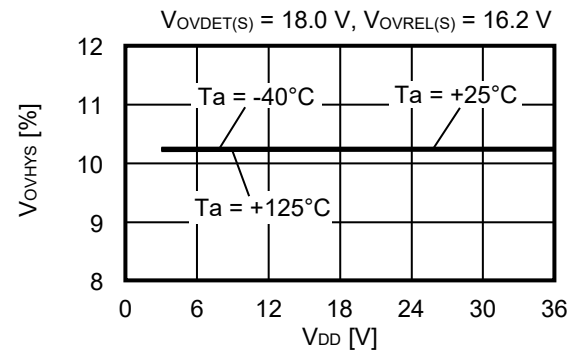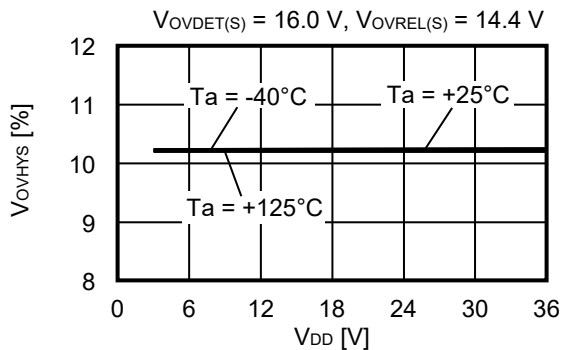
1. 5 Nch transistor output current (I_{OUT}) vs. V_{DS}

1. 5. 1 Undervoltage detection

$V_{UVDET(S)}$ = 4.0 V, $V_{OVDET(S)}$ = 18.0 V,
V_{SENSE} = 3.0 V, Ta = −40°C

$V_{UVDET(S)}$ = 4.0 V, $V_{OVDET(S)}$ = 18.0 V,
V_{SENSE} = 3.0 V, Ta = +25°C

$V_{UVDET(S)}$ = 4.0 V, $V_{OVDET(S)}$ = 18.0 V,
V_{SENSE} = 3.0 V, Ta = +125°C

1. 5. 2 Overvoltage detection

$V_{UVDET(S)}$ = 4.0 V, $V_{OVDET(S)}$ = 18.0 V,
V_{SENSE} = 19.0 V, Ta = −40°C

$V_{UVDET(S)}$ = 4.0 V, $V_{OVDET(S)}$ = 18.0 V,
V_{SENSE} = 19.0 V, Ta = +25°C

$V_{UVDET(S)}$ = 4.0 V, $V_{OVDET(S)}$ = 18.0 V,
V_{SENSE} = 19.0 V, Ta = +125°C
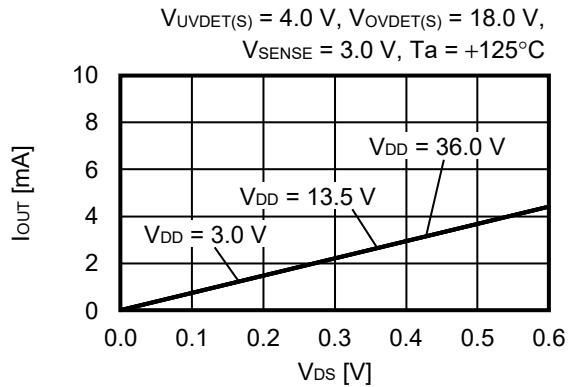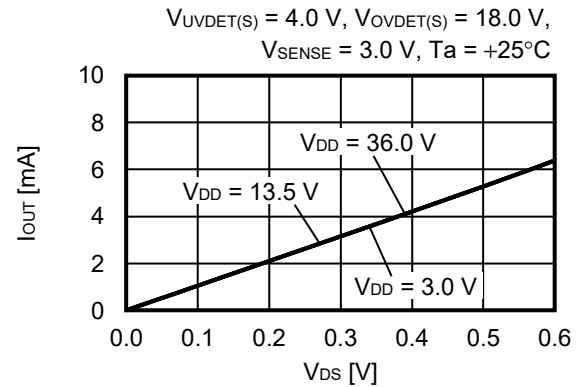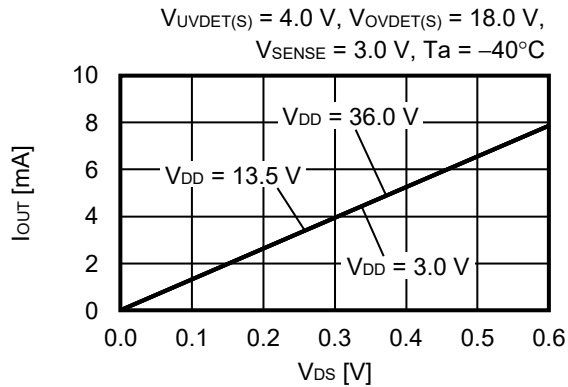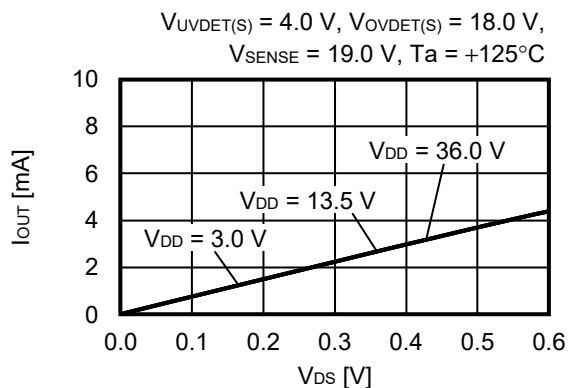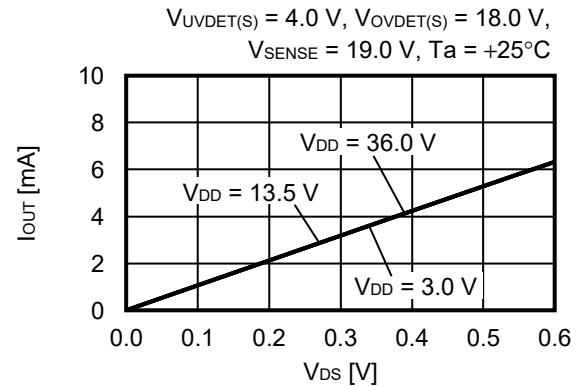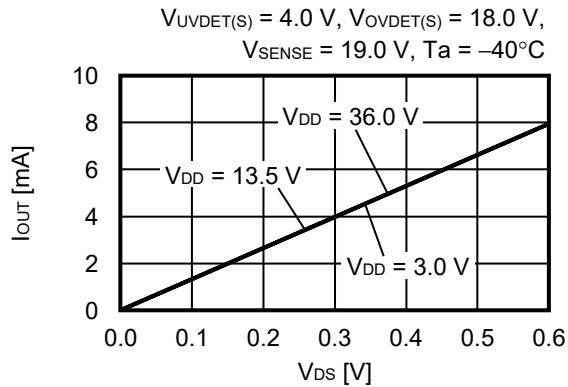
Remark V_{DS}: Drain-to-source voltage of the output transistor

1. 6   Nch transistor output current (I$_{OUT}$) vs. Power supply voltage (V$_{DD}$)

1. 6. 1   Undervoltage detection

V$_{UVDET(S)}$ = 4.0 V, V$_{OVDET(S)}$ = 18.0 V,
V$_{DS}$ = 0.1 V, V$_{SENSE}$ = 3.0 V

1. 6. 2   Overvoltage detection

V$_{UVDET(S)}$ = 4.0 V, V$_{OVDET(S)}$ = 18.0 V,
V$_{DS}$ = 0.1 V, V$_{SENSE}$ = 36.0 V
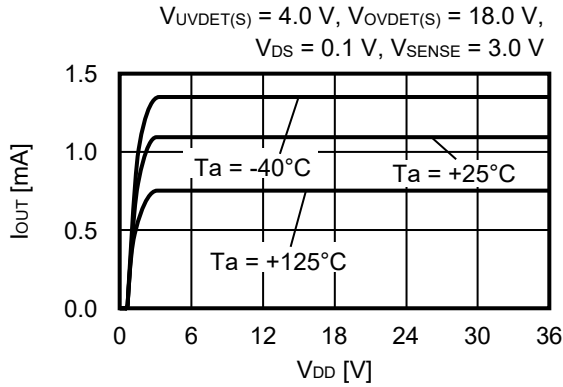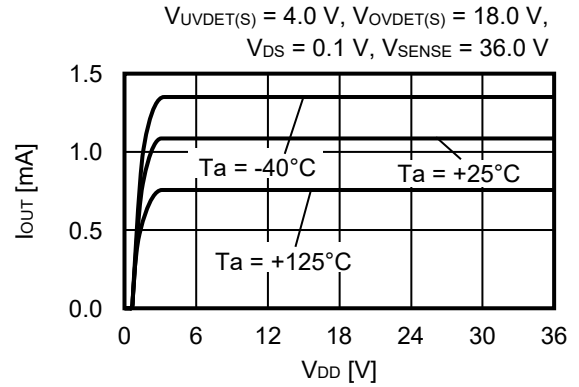
Remark   V$_{DS}$: Drain-to-source voltage of the output transistor

1. 7   Output voltage (V$_{UV}$, V$_{OV}$) vs. SENSE pin voltage (V$_{SENSE}$)

1. 7. 1   Undervoltage detection

V$_{UVDET(S)}$ = 4.0 V, V$_{UVREL(S)}$ = 4.4 V, V$_{DD}$ = 3.0 V,
pull-up to V$_{DD}$, pull-up resistance: 100 kΩ

V$_{UVDET(S)}$ = 4.0 V, V$_{UVREL(S)}$ = 4.4 V, V$_{DD}$ = 3.0 V,
pull-up to 16.0 V, pull-up resistance: 100 kΩ

1. 7. 2   Overvoltage detection

V$_{OVDET(S)}$ = 18.0 V, V$_{OVREL(S)}$ = 16.2 V, V$_{DD}$ = 3.0 V,
pull-up to V$_{DD}$, pull-up resistance: 100 kΩ

V$_{OVDET(S)}$ = 18.0 V, V$_{OVREL(S)}$ = 16.2 V, V$_{DD}$ = 3.0 V,
pull-up to 16.0 V, pull-up resistance: 100 kΩ
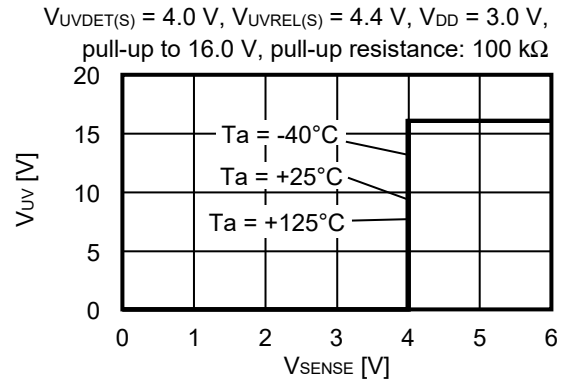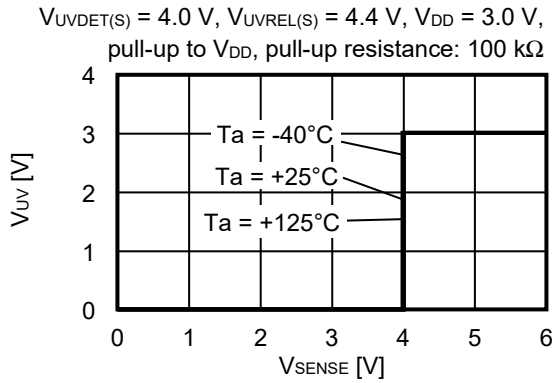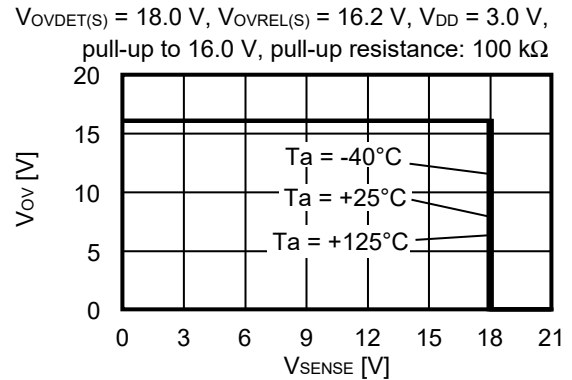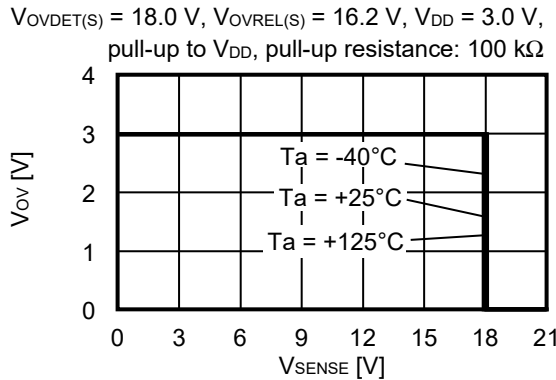
1.8 Dynamic response vs. Output pin capacitance (C_{OUT}) (CD pin; open)

1.8.1 Undervoltage detection

$V_{UVDET(S)}$ = 4.0 V, $V_{UVREL(S)}$ = 4.4 V, V_{DD} = 13.5 V, Ta = −40°C

$V_{UVDET(S)}$ = 4.0 V, $V_{UVREL(S)}$ = 4.4 V, V_{DD} = 13.5 V, Ta = +25°C

$V_{UVDET(S)}$ = 4.0 V, $V_{UVREL(S)}$ = 4.4 V, V_{DD} = 13.5 V, Ta = +125°C

1.8.2 Overvoltage detection

$V_{OVDET(S)}$ = 18.0 V, $V_{OVREL(S)}$ = 16.2 V, V_{DD} = 13.5 V, Ta = −40°C

$V_{OVDET(S)}$ = 18.0 V, $V_{OVREL(S)}$ = 16.2 V, V_{DD} = 13.5 V, Ta = +25°C

$V_{OVDET(S)}$ = 18.0 V, $V_{OVREL(S)}$ = 16.2 V, V_{DD} = 13.5 V, Ta = +125°C
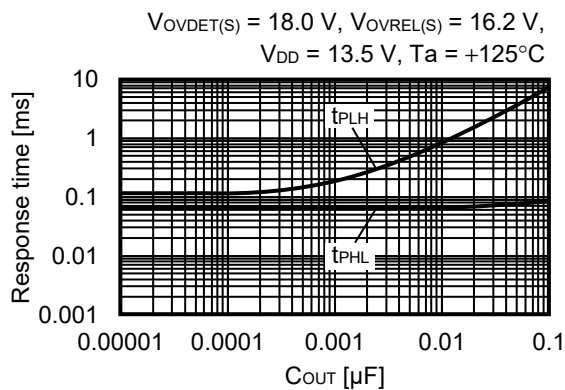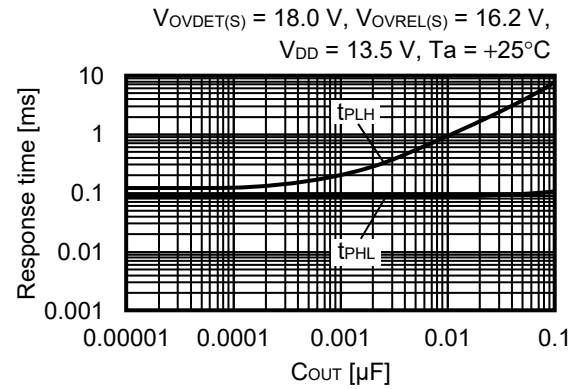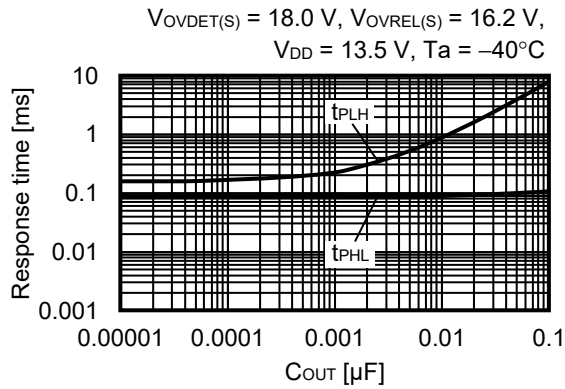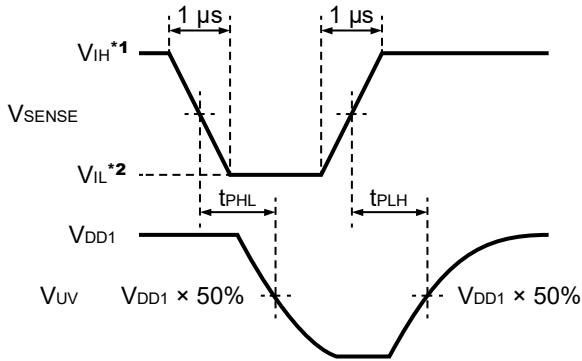
*1. $V_{IH} = V_{UVDET(S)} + 1.0 V$
*2. $V_{IL} = V_{UVDET(S)} - 1.0 V$

**Figure 36 Test Condition of Response Time
(Undervoltage Detection)**
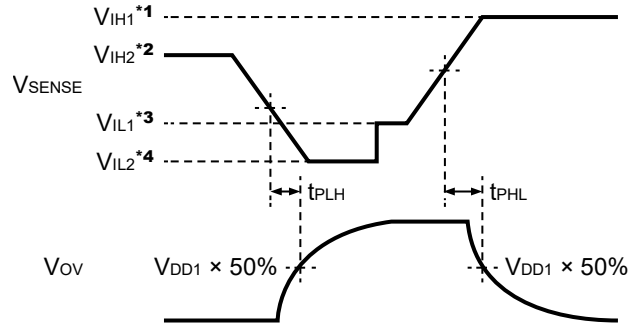
*1. $V_{IH1} = V_{OVDET(S)} + 1.0 V$
*2. $V_{IH2} = V_{OVREL(S)} + 1.0 V$
*3. $V_{IL1} = V_{OVDET(S)} - 1.0 V$
*4. $V_{IL2} = V_{OVREL(S)} - 1.0 V$

**Figure 37 Test Condition of Response Time
(Overvoltage Detection)**
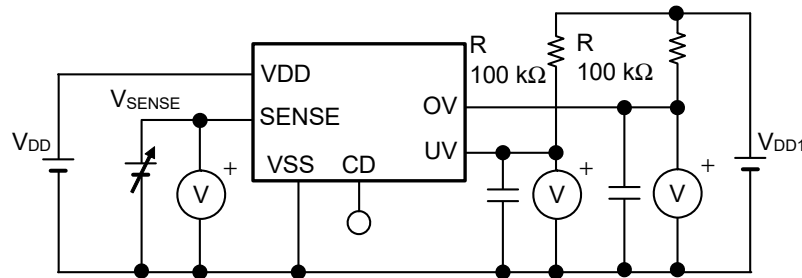
Figure 38 Test Circuit of Response Time

Caution 1. The above connection diagram and constants will not guarantee successful operation. Perform thorough evaluation including the temperature characteristics with an actual application to set the constants.
2. When the CD pin is open, a double pulse may appear at release.
To avoid the double pulse, attach 1 nF or more capacitor to the CD pin.

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2. Supply voltage divider block

2. 1 Output voltage of supply voltage divider block (V_{PMOUT}) vs. Load current (I_{PMOUT})

2. 1. 1 $V_{PMOUT} = V_{SENSE}/6$

$V_{SENSE} = 5.0$ V, $V_{DD} = 3.0$ V, $V_{PMEN} = 3.0$ V

2. 1. 2 $V_{PMOUT} = V_{SENSE}/14$

$V_{SENSE} = 5.0$ V, $V_{DD} = 3.0$ V, $V_{PMEN} = 3.0$ V
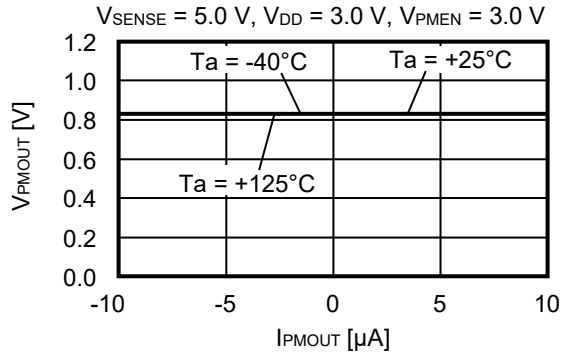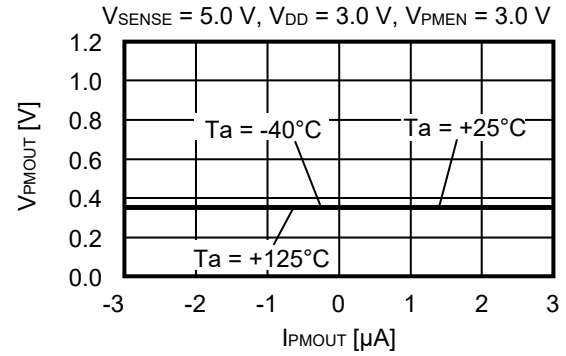
2. 2 Output voltage of supply voltage divider block (V_{PMOUT}) vs. Temperature (Ta)

2. 2. 1 $V_{PMOUT} = V_{SENSE}/6$

$V_{SENSE} = 5.0$ V, $V_{DD} = 3.0$ V, $V_{PMEN} = 3.0$ V

2. 2. 2 $V_{PMOUT} = V_{SENSE}/14$

$V_{SENSE} = 5.0$ V, $V_{DD} = 3.0$ V, $V_{PMEN} = 3.0$ V
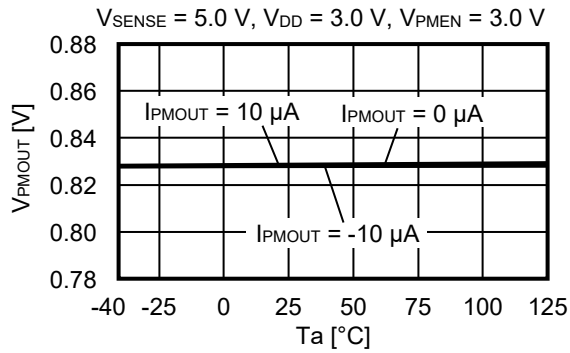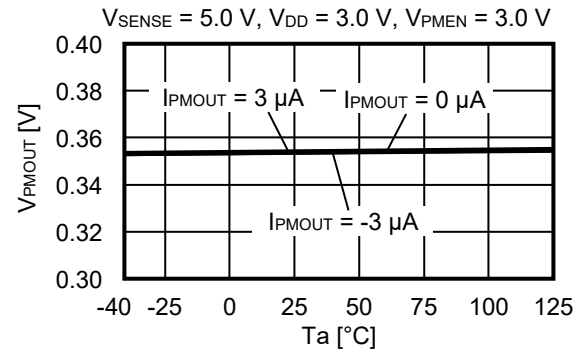
2. 3 Output voltage of supply voltage divider block (V$_{PMOUT}$) vs. SENSE pin voltage (V$_{SENSE}$)

2. 3. 1 V$_{PMOUT}$ = V$_{SENSE}$/6

V$_{DD}$ = 36.0 V, V$_{PMEN}$ = 3.0 V, Ta = −40°C

V$_{DD}$ = 36.0 V, V$_{PMEN}$ = 3.0 V, Ta = +25°C

V$_{DD}$ = 36.0 V, V$_{PMEN}$ = 3.0 V, Ta = +125°C

2. 3. 2 V$_{PMOUT}$ = V$_{SENSE}$/14

V$_{DD}$ = 36.0 V, V$_{PMEN}$ = 3.0 V, Ta = −40°C

V$_{DD}$ = 36.0 V, V$_{PMEN}$ = 3.0 V, Ta = +25°C

V$_{DD}$ = 36.0 V, V$_{PMEN}$ = 3.0 V, Ta = +125°C

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AUTOMOTIVE, 125°C OPERATION, 36 V, SUPPLY VOLTAGE DIVIDED OUTPUT, WINDOW VOLTAGE DETECTOR WITH SENSE PIN REVERSE CONNECTION PROTECTION

Rev.1.2_00   **S-191L/191NxxxxA Series**
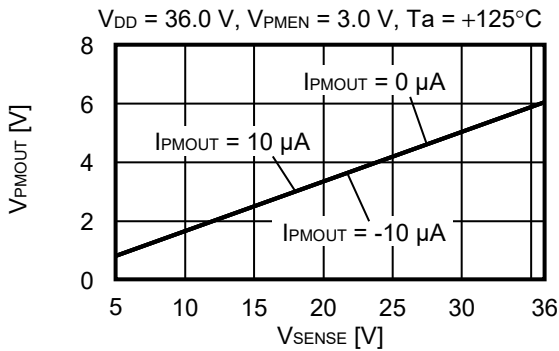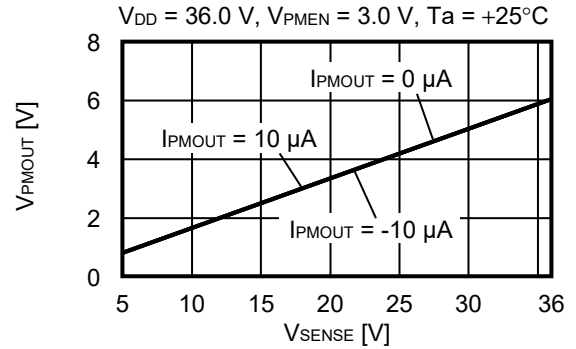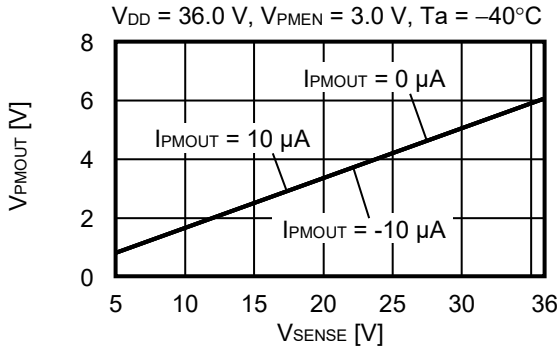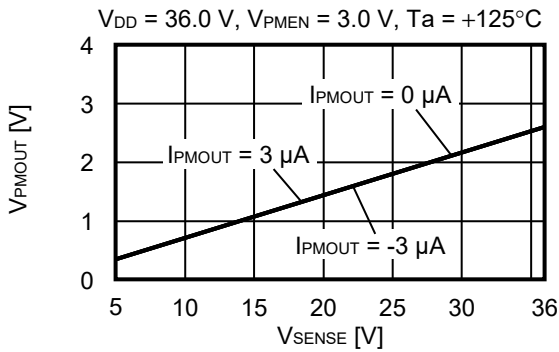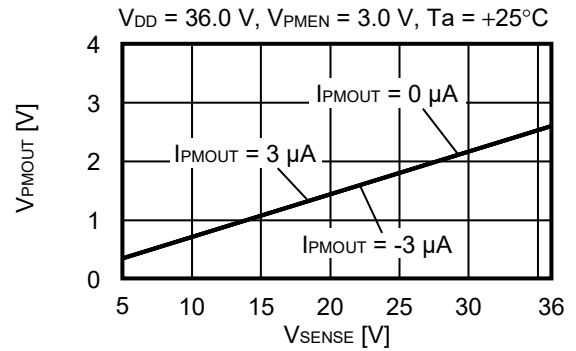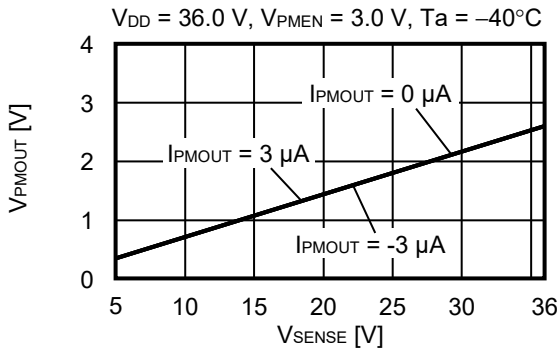
3.   Overall

3. 1   Current consumption (I_{SS1}) vs. Temperature (Ta)

$V_{UVDET(S)}$ = 4.0 V, $V_{OVDET(S)}$ = 18.0 V,
V_{DD} = 13.5 V, V_{SENSE} = 13.5 V,
V_{PMEN} = 0 V (during release)

$V_{UVDET(S)}$ = 10.0 V, $V_{OVDET(S)}$ = 16.0 V,
V_{DD} = 13.5 V, V_{SENSE} = 13.5 V,
V_{PMEN} = 0 V (during release)

$V_{UVDET(S)}$ = 4.0 V, $V_{OVDET(S)}$ = 18.0 V,
V_{DD} = 13.5 V, V_{SENSE} = 3.0 V,
V_{PMEN} = 0 V (during undervoltage detection)

$V_{UVDET(S)}$ = 10.0 V, $V_{OVDET(S)}$ = 16.0 V,
V_{DD} = 13.5 V, V_{SENSE} = 9.0 V,
V_{PMEN} = 0 V (during undervoltage detection)

$V_{UVDET(S)}$ = 4.0 V, $V_{OVDET(S)}$ = 18.0 V,
V_{DD} = 13.5 V, V_{SENSE} = 19.0 V,
V_{PMEN} = 0 V (during overvoltage detection)

$V_{UVDET(S)}$ = 10.0 V, $V_{OVDET(S)}$ = 16.0 V,
V_{DD} = 13.5 V, V_{SENSE} = 17.0 V,
V_{PMEN} = 0 V (during overvoltage detection)

3. 2 Current consumption (I_{SS1}) vs. Power supply voltage (V_{DD}) (No load)

$V_{UVDET(S)}$ = 4.0 V, $V_{OVDET(S)}$ = 18.0 V,
V_{DD} = 0 V → 36.0 V, V_{SENSE} = 13.5 V,
V_{PMEN} = 0 V (during release)

$V_{UVDET(S)}$ = 10.0 V, $V_{OVDET(S)}$ = 16.0 V,
V_{DD} = 0 V → 36.0 V, V_{SENSE} = 13.5 V,
V_{PMEN} = 0 V (during release)

$V_{UVDET(S)}$ = 4.0 V, $V_{OVDET(S)}$ = 18.0 V,
V_{DD} = 0 V → 36.0 V, V_{SENSE} = 3.0 V,
V_{PMEN} = 0 V (during undervoltage detection)

$V_{UVDET(S)}$ = 10.0 V, $V_{OVDET(S)}$ = 16.0 V,
V_{DD} = 0 V → 36.0 V, V_{SENSE} = 9.0 V,
V_{PMEN} = 0 V (during undervoltage detection)

$V_{UVDET(S)}$ = 4.0 V, $V_{OVDET(S)}$ = 18.0 V,
V_{DD} = 0 V → 36.0 V, V_{SENSE} = 19.0 V,
V_{PMEN} = 0 V (during overvoltage detection)

$V_{UVDET(S)}$ = 10.0 V, $V_{OVDET(S)}$ = 16.0 V,
V_{DD} = 0 V → 36.0 V, V_{SENSE} = 17.0 V,
V_{PMEN} = 0 V (during overvoltage detection)

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3. 3　Current consumption (I_{SSP1}) vs. Temperature (Ta)
(No load, during supply voltage divided output operates)

$V_{UVDET(S)}$ = 4.0 V, $V_{OVDET(S)}$ = 18.0 V,
V_{DD} = 13.5 V, V_{SENSE} = 13.5 V,
V_{PMEN} = 13.5 V

$V_{UVDET(S)}$ = 10.0 V, $V_{OVDET(S)}$ = 16.0 V,
V_{DD} = 13.5 V, V_{SENSE} = 13.5 V,
V_{PMEN} = 13.5 V
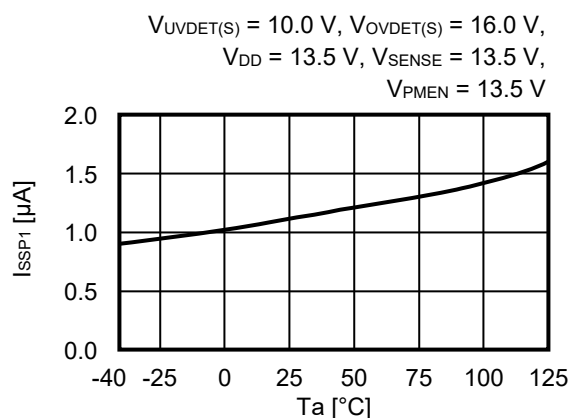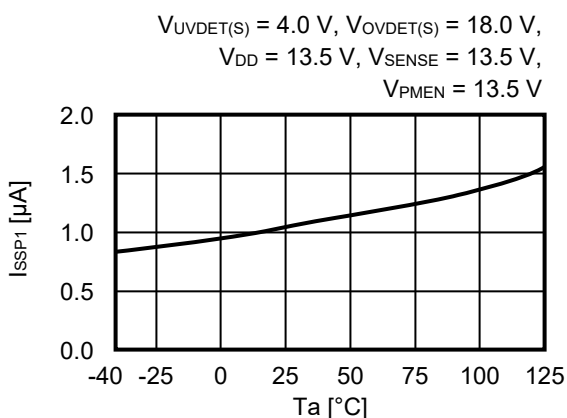
3. 4　Current consumption (I_{SSP1}) vs. Power supply voltage (V_{DD})
(No load, during supply voltage divided output operates)

$V_{UVDET(S)}$ = 4.0 V, $V_{OVDET(S)}$ = 18.0 V,
V_{DD} = 0 V → 36.0 V, V_{SENSE} = 13.5 V,
V_{PMEN} = 13.5 V

$V_{UVDET(S)}$ = 4.0 V, $V_{OVDET(S)}$ = 18.0 V,
V_{DD} = 0 V → 36.0 V, V_{SENSE} = 13.5 V,
V_{PMEN} = 13.5 V

$V_{UVDET(S)}$ = 10.0 V, $V_{OVDET(S)}$ = 16.0 V,
V_{DD} = 0 V → 36.0 V, V_{SENSE} = 13.5 V,
V_{PMEN} = 13.5 V

$V_{UVDET(S)}$ = 10.0 V, $V_{OVDET(S)}$ = 16.0 V,
V_{DD} = 0 V → 36.0 V, V_{SENSE} = 13.5 V,
V_{PMEN} = 13.5 V

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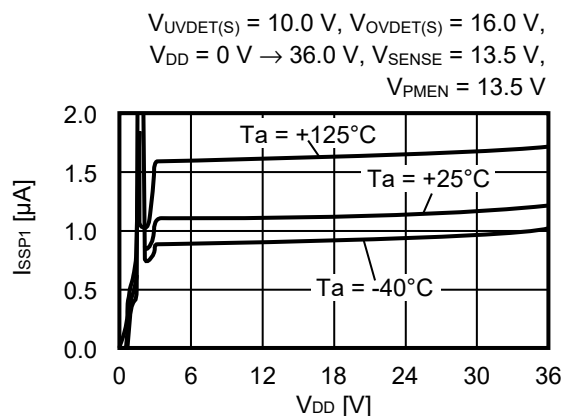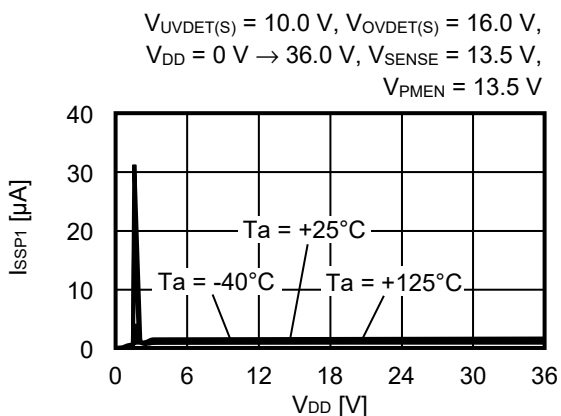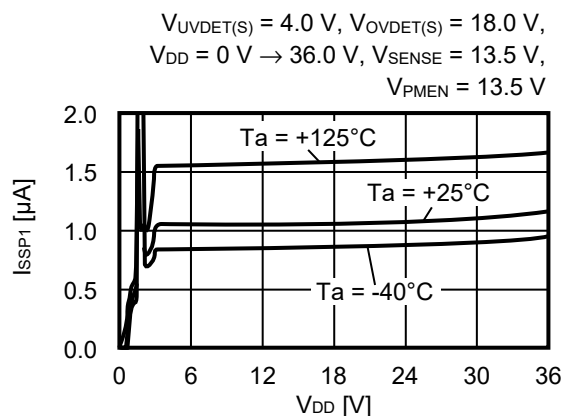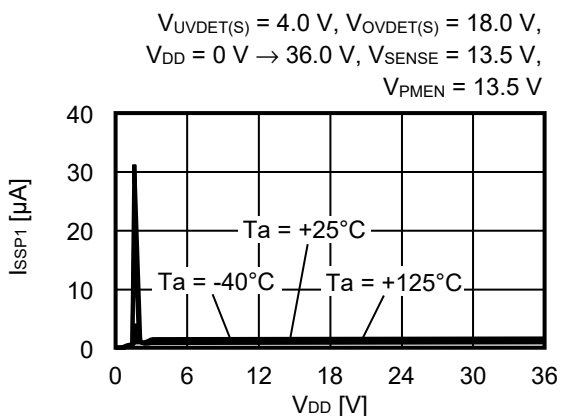
■ Reference Data

1. Detection response time (t_{RESET}) vs. Temperature (Ta)

1. 1 Undervoltage detection

$V_{UVDET(S)}$ = 4.0 V, $V_{UVREL(S)}$ = 4.4 V,
V_{DD} = 13.5 V, C_D = 3.3 nF

1. 2 Overvoltage detection

$V_{OVDET(S)}$ = 18.0 V, $V_{OVREL(S)}$ = 16.2 V,
V_{DD} = 13.5 V, C_D = 3.3 nF
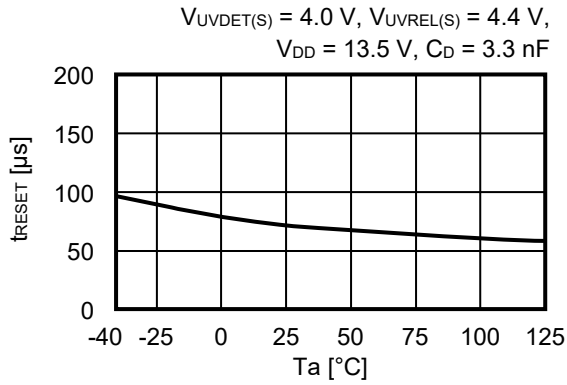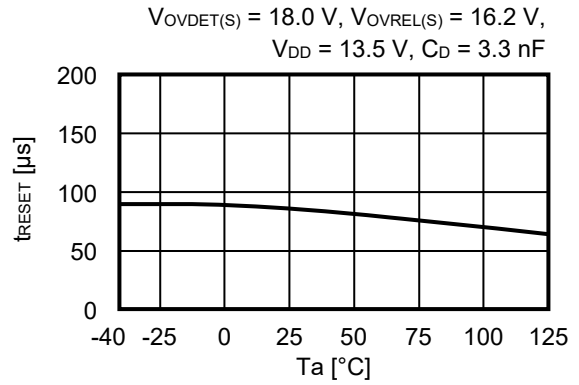
2. Detection response time (t_{RESET}) vs. Power supply voltage (V_{DD})

2. 1 Undervoltage detection

$V_{UVDET(S)}$ = 4.0 V, $V_{UVREL(S)}$ = 4.4 V,
C_D = 3.3 nF

Ta = -40°C   Ta = +25°C

Ta = +125°C

2. 2 Overvoltage detection

$V_{OVDET(S)}$ = 18.0 V, $V_{OVREL(S)}$ = 16.2 V,
C_D = 3.3 nF

Ta = -40°C   Ta = +25°C

Ta = +125°C
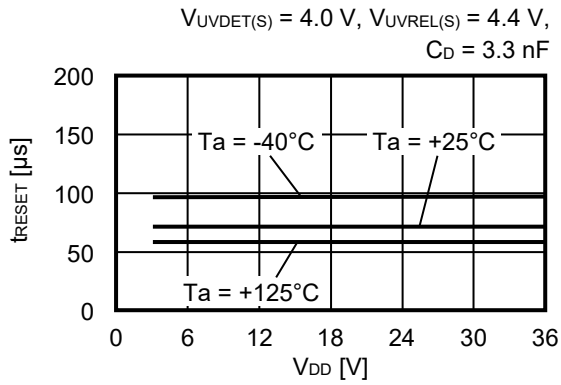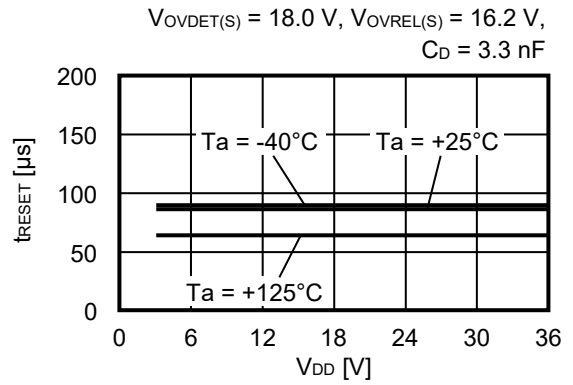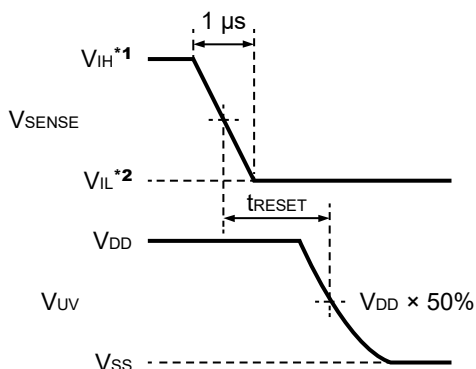
*1. $V_{IH} = V_{UVDET(S)} + 1.0$ V
*2. $V_{IL} = V_{UVDET(S)} - 1.0$ V

Figure 39   Test Condition of Detection Response Time (Undervoltage Detection)
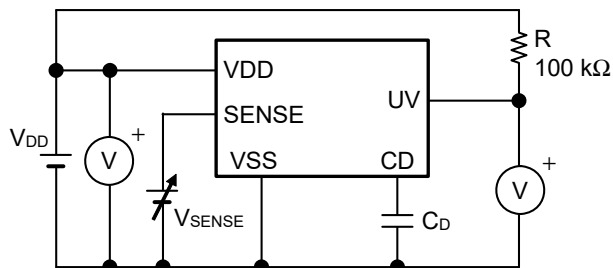
Figure 40   Test Circuit of Detection Response Time (Undervoltage Detection)
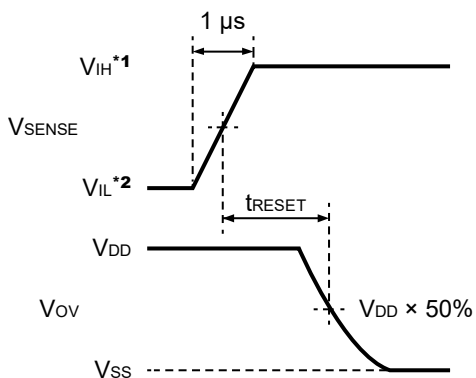
*1. $V_{IH} = V_{OVDET(S)} + 1.0$ V
*2. $V_{IL} = V_{OVDET(S)} - 1.0$ V

Figure 41   Test Condition of Detection Response Time (Overvoltage Detection)
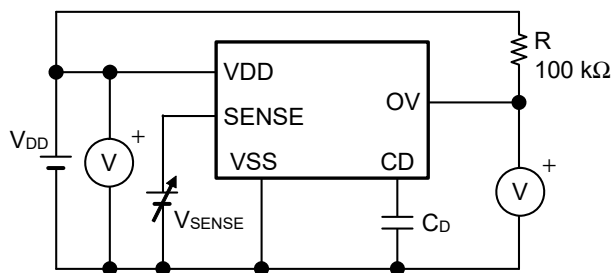
Figure 42   Test Circuit of Detection Response Time (Overvoltage Detection)

Caution   The above connection diagram and constants will not guarantee successful operation. Perform thorough evaluation including the temperature characteristics with an actual application to set the constants.

3. Release delay time (t_{DELAY}) vs. Temperature (Ta)

3. 1 Undervoltage detection

$V_{UVDET(S)}$ = 4.0 V, $V_{UVREL(S)}$ = 4.4 V,
V_{DD} = 13.5 V, C_D = 3.3 nF

3. 2 Overvoltage detection

$V_{OVDET(S)}$ = 18.0 V, $V_{OVREL(S)}$ = 16.2 V,
V_{DD} = 13.5 V, C_D = 3.3 nF
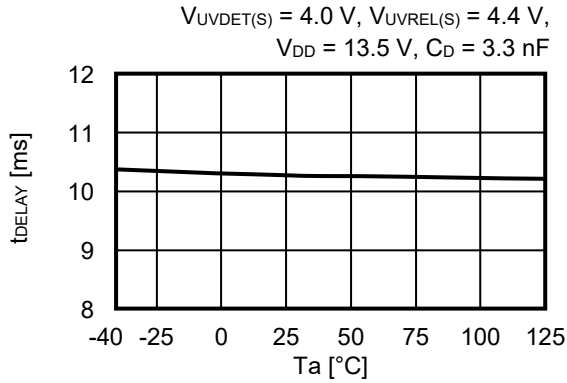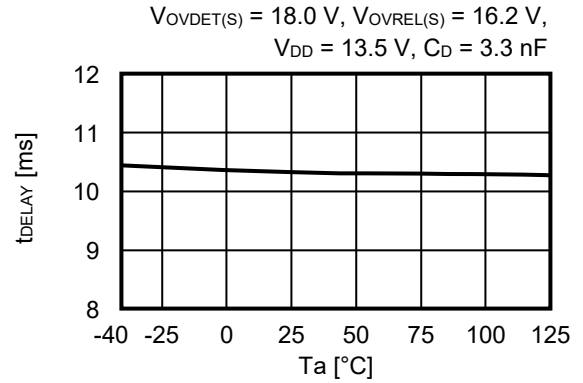
4. Release delay time (t_{DELAY}) vs. Power supply voltage (V_{DD})

4. 1 Undervoltage detection

$V_{UVDET(S)}$ = 4.0 V, $V_{UVREL(S)}$ = 4.4 V,
C_D = 3.3 nF

4. 2 Overvoltage detection

$V_{OVDET(S)}$ = 18.0 V, $V_{OVREL(S)}$ = 16.2 V,
C_D = 3.3 nF
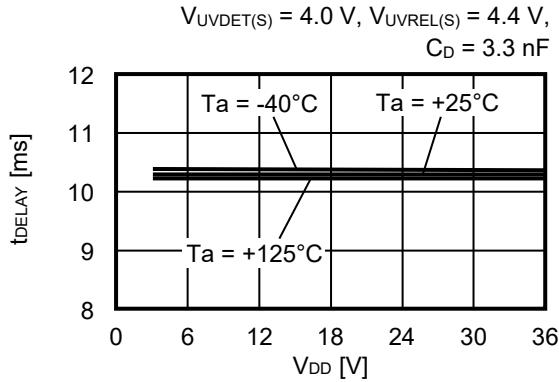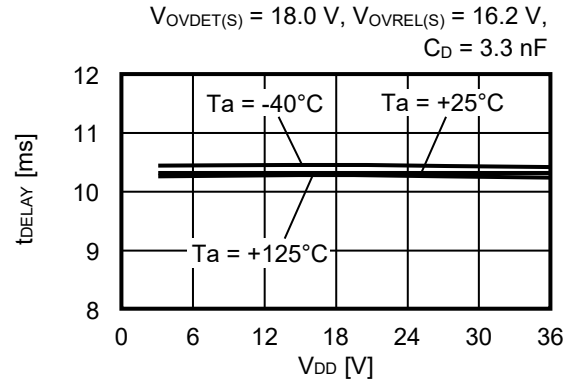
5. Release delay time (t_{DELAY}) vs. CD pin capacitance (C_D) (Without output pin capacitance)

5. 1 Undervoltage detection

$V_{UVDET(S)}$ = 4.0 V, $V_{UVREL(S)}$ = 4.4 V

5. 2 Overvoltage detection

$V_{OVDET(S)}$ = 18.0 V, $V_{OVREL(S)}$ = 16.2 V

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AUTOMOTIVE, 125°C OPERATION, 36 V, SUPPLY VOLTAGE DIVIDED OUTPUT, WINDOW VOLTAGE DETECTOR WITH SENSE PIN REVERSE CONNECTION PROTECTION

Rev.1.2_00   **S-191L/191NxxxxA Series**
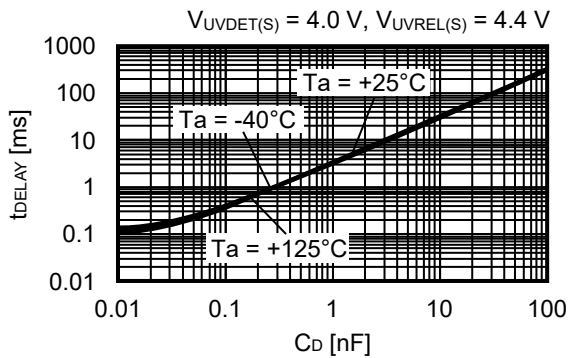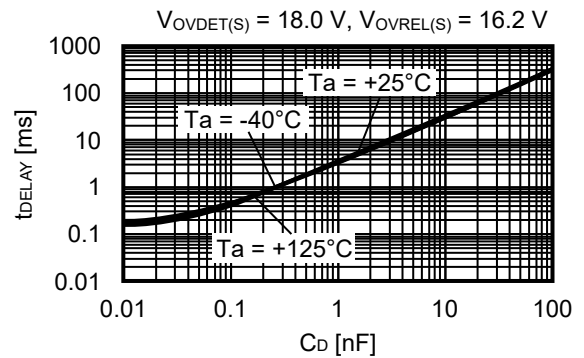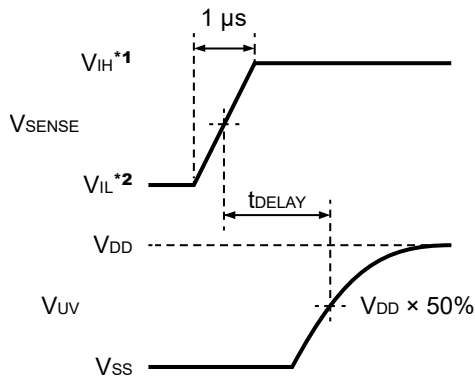
*1. $V_{IH} = V_{UVREL(S)} + 1.0$ V
*2. $V_{IL} = V_{UVREL(S)} - 1.0$ V

Figure 43   Test Condition of Release Delay Time (Undervoltage Detection)
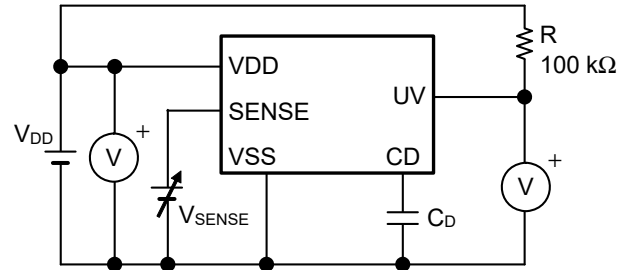
Figure 44   Test Circuit of Release Delay Time (Undervoltage Detection)
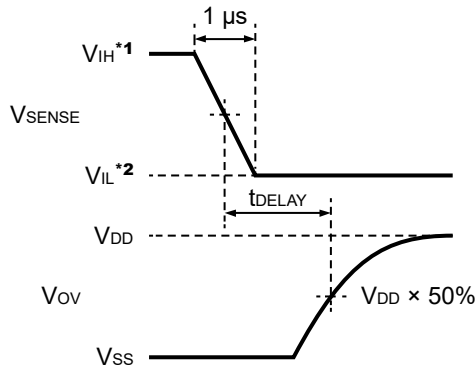
*1. $V_{IH} = V_{OVREL(S)} + 1.0$ V
*2. $V_{IL} = V_{OVREL(S)} - 1.0$ V

Figure 45   Test Condition of Release Delay Time (Overvoltage Detection)
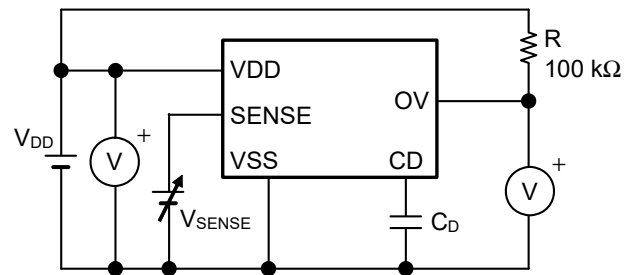
Figure 46   Test Circuit of Release Delay Time (Overvoltage Detection)

Caution   The above connection diagram and constants will not guarantee successful operation. Perform thorough evaluation including the temperature characteristics with an actual application to set the constants.

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6. Transient response characteristics of PMEN pin (Ta = +25°C)

6. 1 $V_{PMOUT} = V_{SENSE}/6$

$V_{DD} = V_{SENSE} = 5.0$ V, $C_{PM} = 0.22$ µF,
$V_{PMEN} = 0$ V $\leftrightarrow$ 5.0 V ($t_r = t_f = 1.0$ µs)
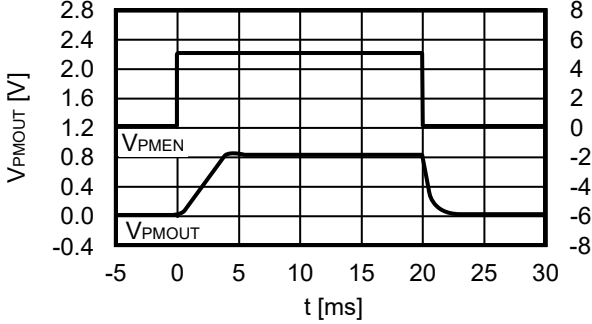
$V_{DD} = V_{SENSE} = 18.0$ V, $C_{PM} = 0.22$ µF,
$V_{PMEN} = 0$ V $\leftrightarrow$ 18.0 V ($t_r = t_f = 1.0$ µs)
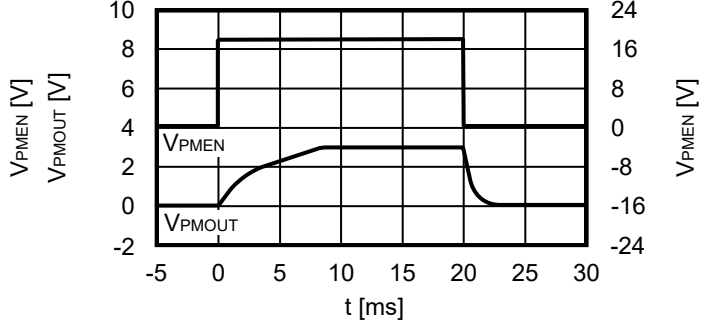
6. 2 $V_{PMOUT} = V_{SENSE}/14$

$V_{DD} = V_{SENSE} = 5.0$ V, $C_{PM} = 0.22$ µF,
$V_{PMEN} = 0$ V $\leftrightarrow$ 5.0 V ($t_r = t_f = 1.0$ µs)
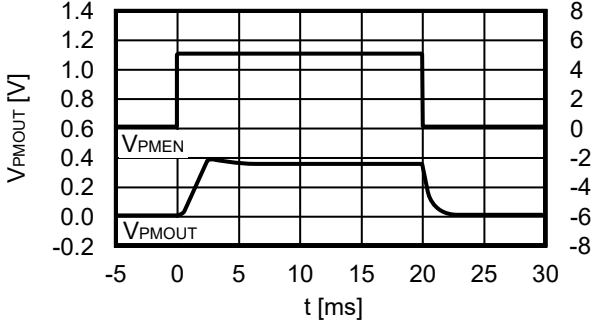
$V_{DD} = V_{SENSE} = 18.0$ V, $C_{PM} = 0.22$ µF,
$V_{PMEN} = 0$ V $\leftrightarrow$ 18.0 V ($t_r = t_f = 1.0$ µs)
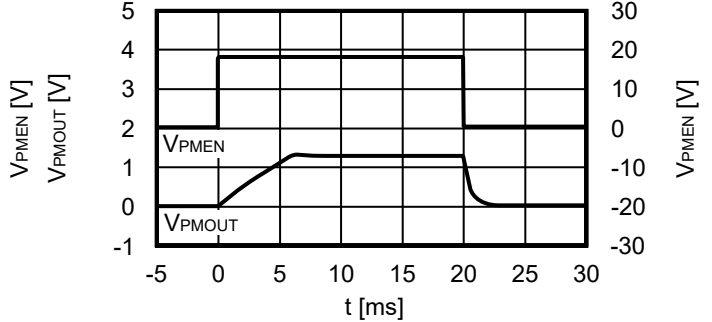
7. Example of equivalent series resistance vs. Load current characteristics (Ta = −40°C to +125°C)

7. 1 $V_{PMOUT} = V_{SENSE}/6$, $V_{SENSE}/8$, $V_{SENSE}/12$

$C_{PM} = 0.1$ µF
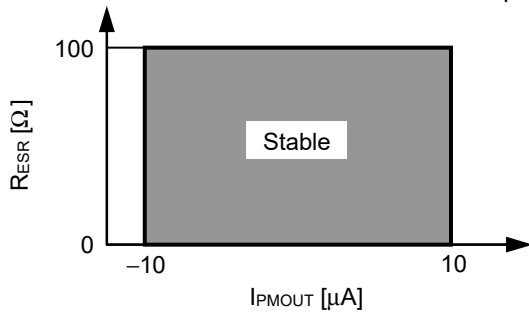
Figure 47

7. 2 $V_{PMOUT} = V_{SENSE}/14$

$C_{PM} = 0.1$ µF
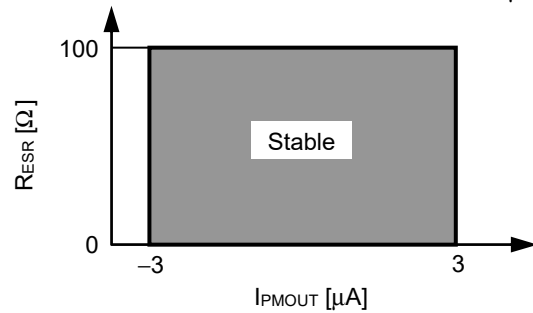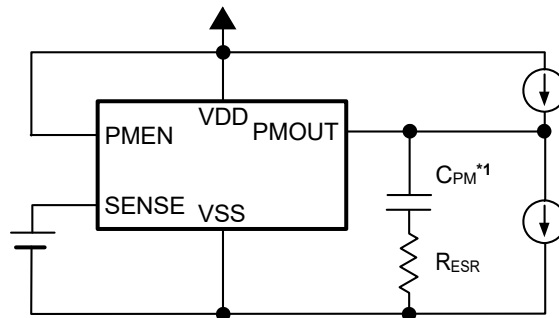
Figure 48

*1. C_{PM}: TDK Corporation CGA4J2X8R1H104K

Figure 49

AUTOMOTIVE, 125°C OPERATION, 36 V, SUPPLY VOLTAGE DIVIDED OUTPUT, WINDOW VOLTAGE DETECTOR WITH SENSE PIN REVERSE CONNECTION PROTECTION

Rev.1.2_00 **S-191L/191NxxxxA Series**

8. Load dump characteristics (Ta = +25°C)

8. 1 $V_{UVDET(S)}$ = 4.0 V

$V_{DD} = V_{SENSE} = 13.5 \text{ V} \leftrightarrow 45.0 \text{ V}$,
$V_{DD1} = 5.0 \text{ V}, C_D = 3.3 \text{ nF}$
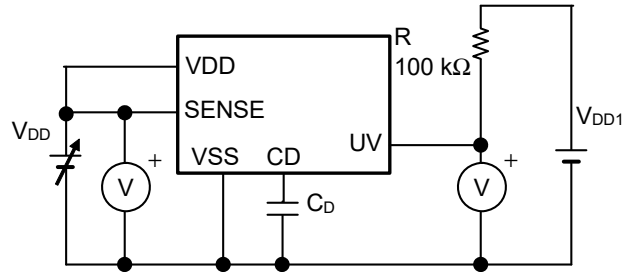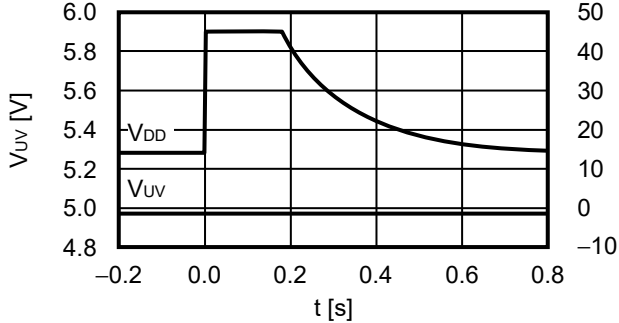
Figure 50

8. 2 $V_{OVDET(S)}$ = 18.0 V

$V_{DD} = V_{SENSE} = 13.5 \text{ V} \leftrightarrow 45.0 \text{ V}$,
$V_{DD1} = 5.0 \text{ V}, C_D = 3.3 \text{ nF}$
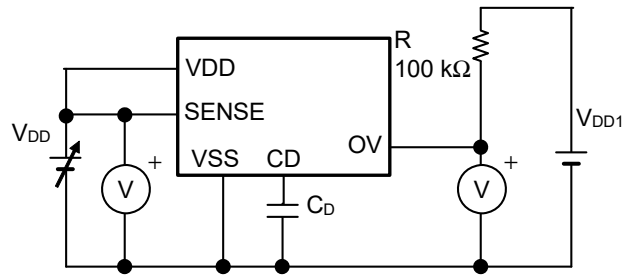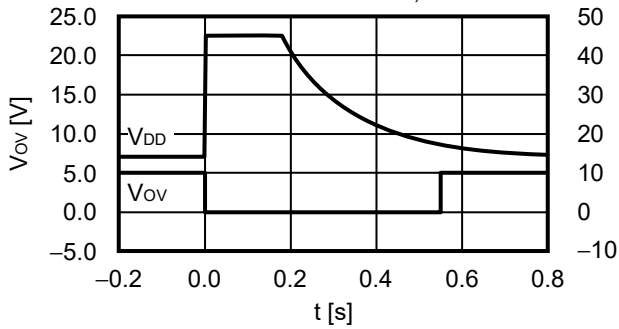
Figure 51

8. 3 $V_{PMOUT} = V_{SENSE}/12$

$V_{DD} = V_{SENSE} = V_{PMEN} = 13.5 \text{ V} \leftrightarrow 45.0 \text{ V}$,
$C_{PM} = 0.1 \text{ μF}, C_D = 3.3 \text{ nF}$
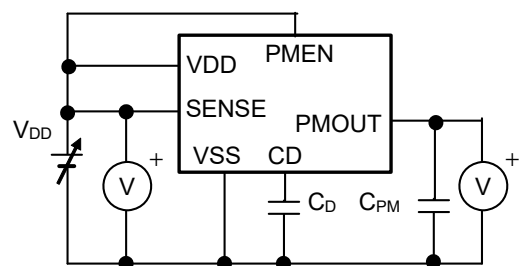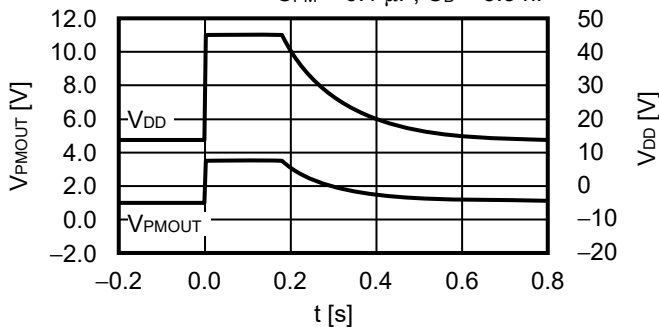
Figure 52

■ Power Dissipation

HTMSOP-8   **HSNT-8(2030)**

T_j = +150°C max. T_j = +150°C max.
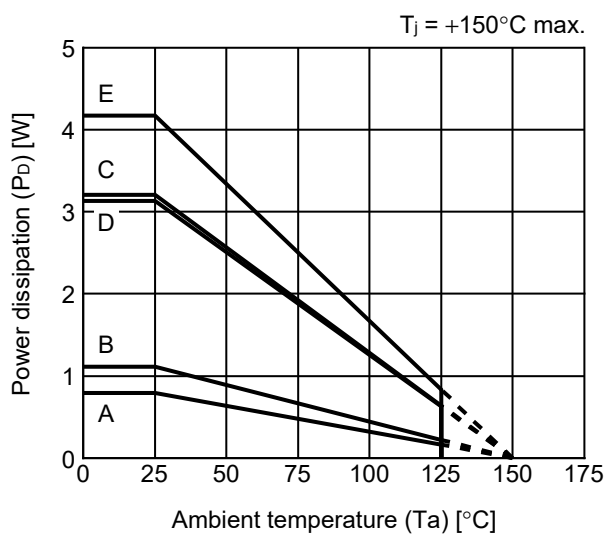
Board	Power Dissipation (P_D)
A	0.79 W
B	1.11 W
C	3.21 W
D	3.13 W
E	4.17 W
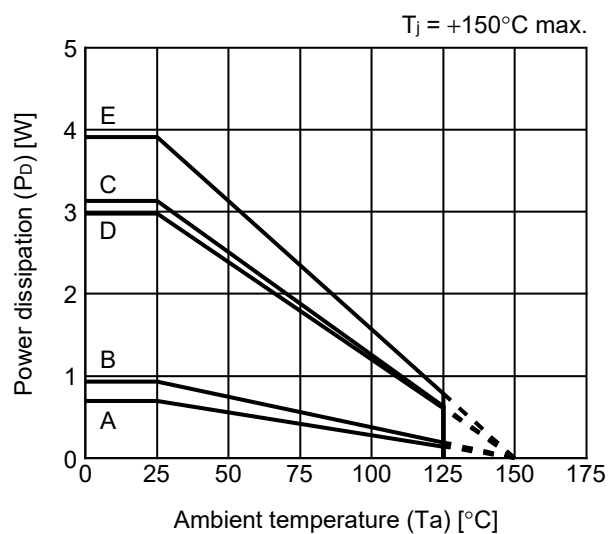
Board	Power Dissipation (P_D)
A	0.69 W
B	0.93 W
C	3.13 W
D	2.98 W
E	3.91 W

ABLIC Inc.

HTMSOP-8 Test Board

◯ IC Mount Area

(1) Board A

Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
Material		FR-4
Number of copper foil layer		2
Copper foil layer [mm]	1	Land pattern and wiring for testing: t0.070
	2	-
	3	-
	4	74.2 x 74.2 x t0.070
Thermal via		-

(2) Board B

Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
Material		FR-4
Number of copper foil layer		4
Copper foil layer [mm]	1	Land pattern and wiring for testing: t0.070
	2	74.2 x 74.2 x t0.035
	3	74.2 x 74.2 x t0.035
	4	74.2 x 74.2 x t0.070
Thermal via		-

(3) Board C

Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
Material		FR-4
Number of copper foil layer		4
Copper foil layer [mm]	1	Land pattern and wiring for testing: t0.070
	2	74.2 x 74.2 x t0.035
	3	74.2 x 74.2 x t0.035
	4	74.2 x 74.2 x t0.070
Thermal via		Number: 4 Diameter: 0.3 mm

enlarged view

No. HTMSOP8-A-Board-SD-1.0

ABLIC Inc.

HTMSOP-8 Test Board

(4) Board D

Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
Material		FR-4
Number of copper foil layer		4
Copper foil layer [mm]	1	Pattern for heat radiation: 2000mm^2 t0.070
	2	74.2 x 74.2 x t0.035
	3	74.2 x 74.2 x t0.035
	4	74.2 x 74.2 x t0.070
Thermal via		-

enlarged view

(5) Board E

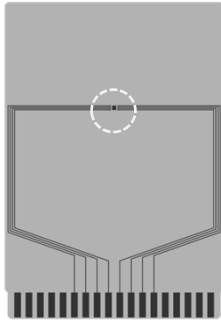| Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
Material		FR-4
Number of copper foil layer		4
Copper foil layer [mm]	1	Pattern for heat radiation: 2000mm^2 t0.070
	2	74.2 x 74.2 x t0.035
	3	74.2 x 74.2 x t0.035
	4	74.2 x 74.2 x t0.070
Thermal via		Number: 4 Diameter: 0.3 mm

enlarged view

No. HTMSOP8-A-Board-SD-1.0

ABLIC Inc.

HSNT-8(2030) Test Board

(1) Board A

Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
Material		FR-4
Number of copper foil layer		2
Copper foil layer [mm]	1	Land pattern and wiring for testing: t0.070
	2	-
	3	-
	4	74.2 x 74.2 x t0.070
Thermal via		-

(2) Board B

Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
Material		FR-4
Number of copper foil layer		4
Copper foil layer [mm]	1	Land pattern and wiring for testing: t0.070
	2	74.2 x 74.2 x t0.035
	3	74.2 x 74.2 x t0.035
	4	74.2 x 74.2 x t0.070
Thermal via		-

(3) Board C

Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
Material		FR-4
Number of copper foil layer		4
Copper foil layer [mm]	1	Land pattern and wiring for testing: t0.070
	2	74.2 x 74.2 x t0.035
	3	74.2 x 74.2 x t0.035
	4	74.2 x 74.2 x t0.070
Thermal via		Number: 4 Diameter: 0.3 mm

enlarged view

No. HSNT8-A-Board-SD-2.0

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HSNT-8(2030) Test Board

(4) Board D

Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
Material		FR-4
Number of copper foil layer		4
Copper foil layer [mm]	1	Pattern for heat radiation: 2000mm^2 t0.070
	2	74.2 x 74.2 x t0.035
	3	74.2 x 74.2 x t0.035
	4	74.2 x 74.2 x t0.070
Thermal via		-

enlarged view

(5) Board E

Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
Material		FR-4
Number of copper foil layer		4
Copper foil layer [mm]	1	Pattern for heat radiation: 2000mm^2 t0.070
	2	74.2 x 74.2 x t0.035
	3	74.2 x 74.2 x t0.035
	4	74.2 x 74.2 x t0.070
Thermal via		Number: 4 Diameter: 0.3 mm

enlarged view

No. HSNT8-A-Board-SD-2.0

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2.90±0.2

8   5

1   4

2.8

4.0±0.2

0.45±0.2

0.13±0.1

1.85

1.70

0.6±0.1

0.2±0.1

0.08±0.05

0.65±0.1

No. FP008-A-P-SD-2.0

TITLE	HTMSOP8-A-PKG Dimensions
No.	FP008-A-P-SD-2.0
ANGLE	⊕ ⊏
UNIT	mm

ABLIC Inc.

2.00±0.05

4.00±0.1

4.00±0.1

1.5 +0.1 -0

1.75±0.1

1.00±0.1

5.50±0.05

12.0 +0.2 -0.1

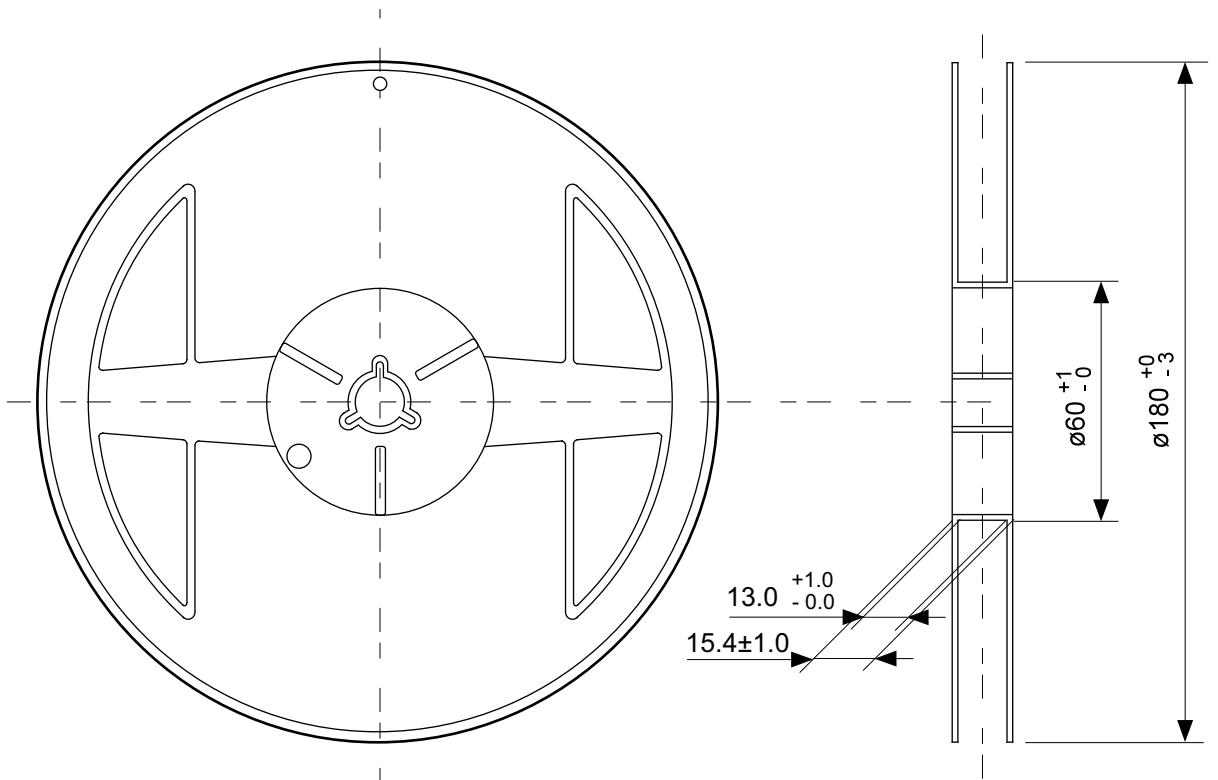4.25±0.05

1.05±0.05

0.30±0.05

3.25±0.05

4 1

5 8

Feed direction
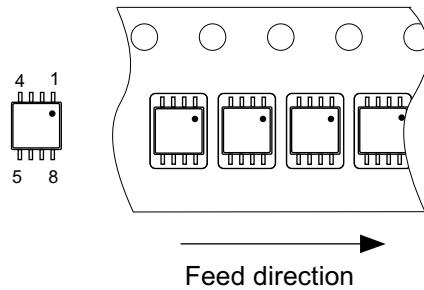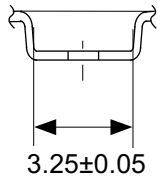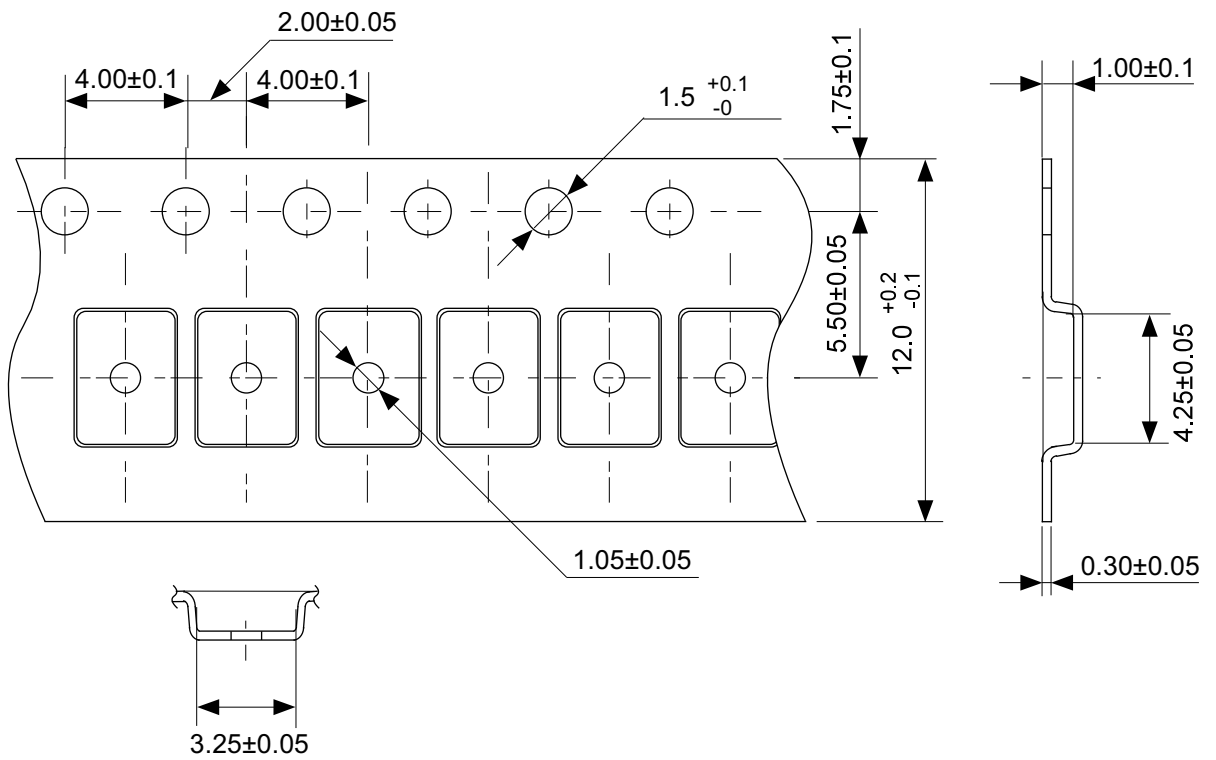
No. FP008-A-C-SD-1.0

TITLE	HTMSOP8-A-Carrier Tape
No.	FP008-A-C-SD-1.0
ANGLE	
UNIT	mm

ABLIC Inc.

Enlarged drawing in the central part

ø21±0.8　　ø13±0.2

2±0.5

(60°)　　(60°)

13.0 $^{+1.0}_{-0.0}$

15.4±1.0

ø60 $^{+1}_{-0}$

ø180 $^{+0}_{-.3}$
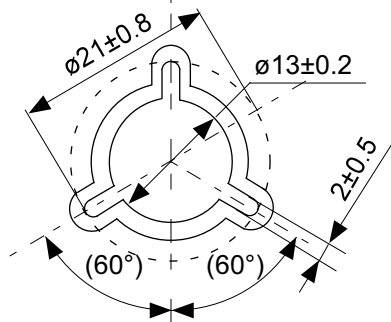
No. FP008-A-R-SD-2.0

TITLE	HTMSOP8-A-Reel		
No.	FP008-A-R-SD-2.0		
ANGLE		QTY.	4,000
UNIT	mm		
	ABLIC Inc.		

0.35

0.85

1.90

1.70

4.60

0.85

0.65   0.65   0.65
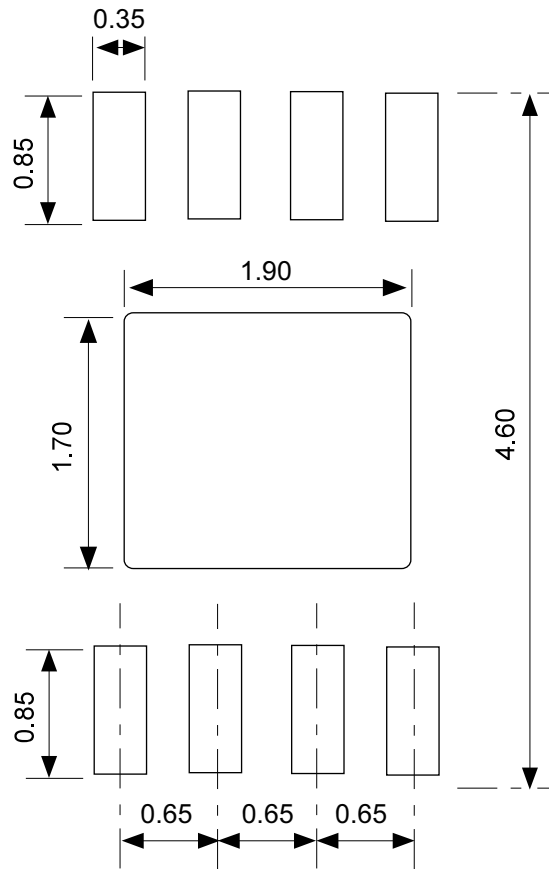
No. FP008-A-L-SD-2.0

TITLE	HTMSOP8-A -Land Recommendation
No.	FP008-A-L-SD-2.0
ANGLE	
UNIT	mm

ABLIC Inc.

2.0±0.1

8   5

3.0±0.1

1   4

(0.10)

(0.10)

0.08 +0.05 -0.02

(0.38)

(1.70)

(1.40)

0.5

※

0.5max.

0.23±0.1
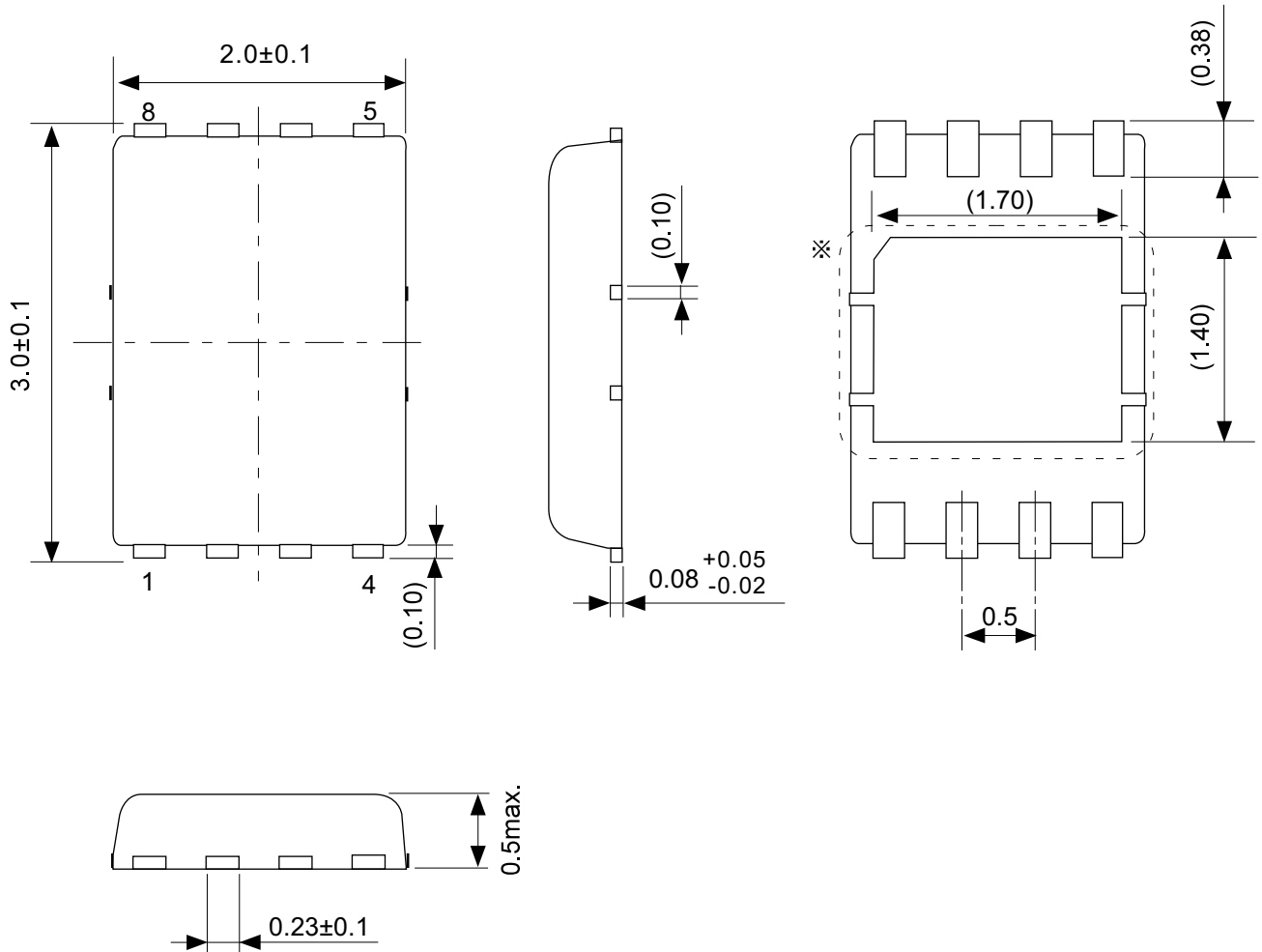
※ The heat sink of back side has different electric
potential depending on the product.
Confirm specifications of each product.
Do not use it as the function of electrode.

No. PP008-A-P-SD-2.0

TITLE	HSNT-8-A-PKG Dimensions
No.	PP008-A-P-SD-2.0
ANGLE	⊕ ◁
UNIT	mm

ABLIC Inc.

ø1.5 $^{+0.1}_{-0}$ 2.0±0.05 4.0±0.1 1.75±0.1 0.25±0.05

3.5±0.05

8.0 $^{+0.3}_{-0.1}$

3.3±0.05

ø1.0 $^{+0.1}_{-0}$

0.60±0.05

2.3±0.05

4.0±0.1

4 3 2 1

5 6 7 8
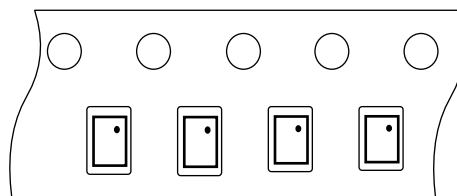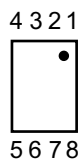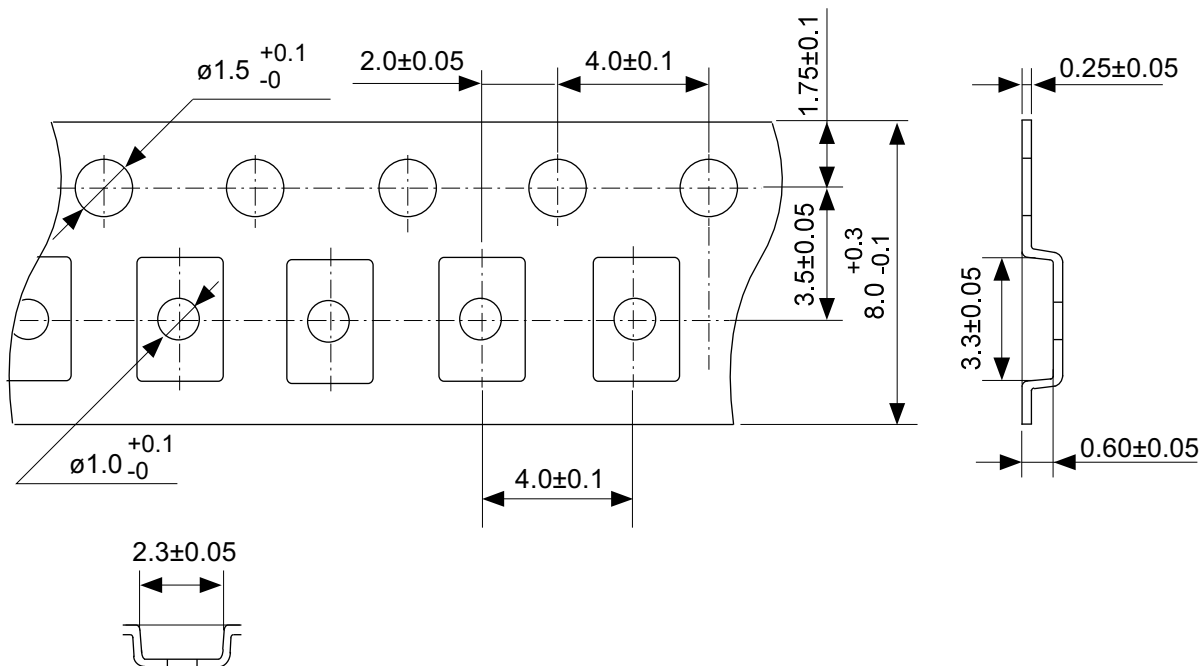
Feed direction

No. PP008-A-C-SD-1.0

TITLE	HSNT-8-A-Carrier Tape
No.	PP008-A-C-SD-1.0
ANGLE	
UNIT	mm

ABLIC Inc.

ø60 +1 -0

ø180 +0 -3

9.0 +1.0 -0.0

11.4±1.0

Enlarged drawing in the central part

ø21±0.8

ø13±0.2

2±0.5

(60°)   (60°)
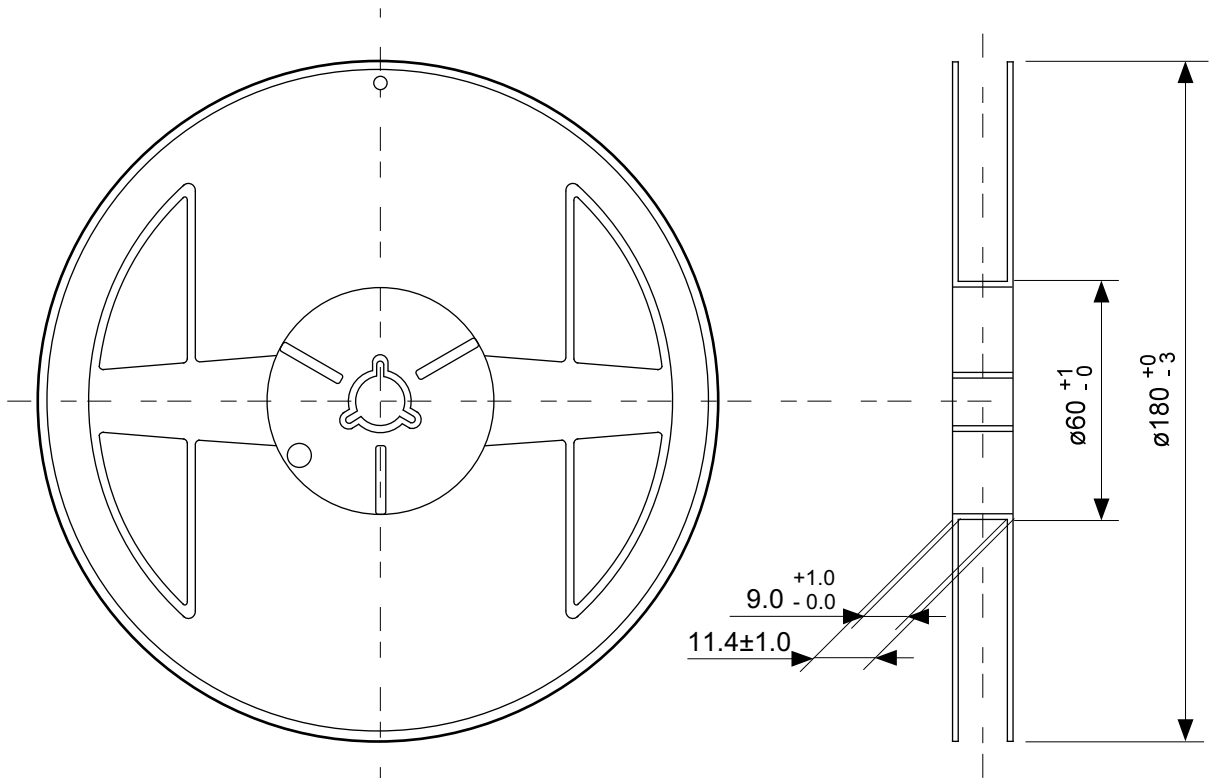
No. PP008-A-R-SD-2.0

TITLE	HSNT-8-A-Reel		
No.	PP008-A-R-SD-2.0		
ANGLE		QTY.	5,000
UNIT	mm		

ABLIC Inc.

1.4

2.75

1.6

0.55

0.30

0.50
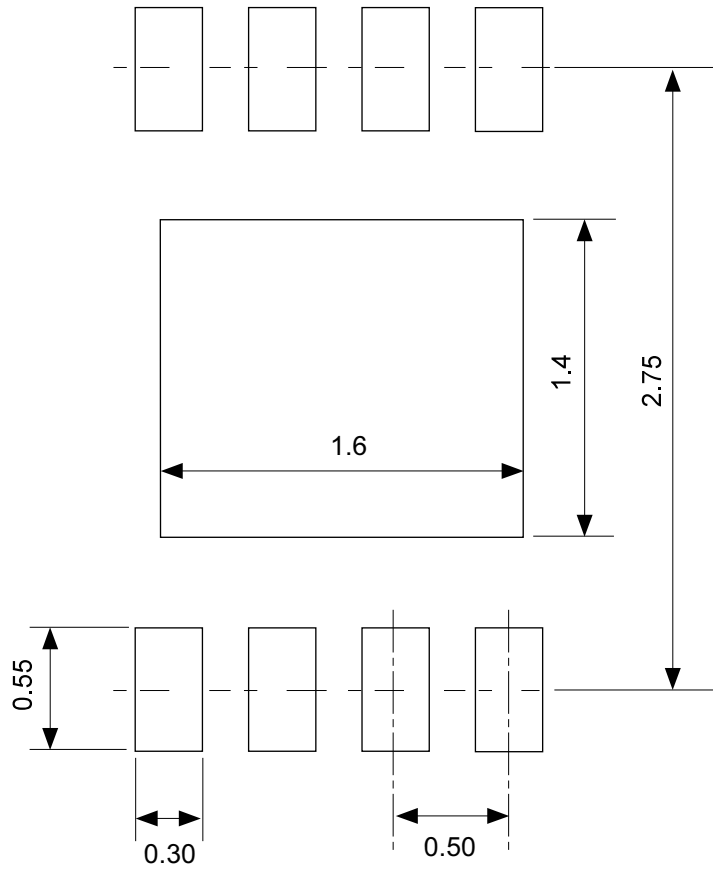
No. PP008-A-L-SD-1.0

TITLE	HSNT-8-A -Land Recommendation
No.	PP008-A-L-SD-1.0
ANGLE	
UNIT	mm

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2.4-2019.07

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